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Ferroelectricity Newsletter

A quarterly update on what's happening in the field of ferroelectricity

Volume 6, Number 4

Fall 1998

TRIPLE MONTREUX CONFERENCE EXPANDS NOT ONLY THE SCIENTIFIC HORIZON

As we complete the sixth year of gathering information on what's happening in the field of ferroelectricity around the world, we find that the explosive growth in this area is visually reflected in the length of this newsletter: Never before did we have a single issue with 40 pages.

The reason is quite simple. We wanted to give you some idea of the breadth and depth of what was going on in Montreux last August at **Electroceramics VI**, the **European Conference on Applications of Polar Dielectrics (ECAPD IV)**, and the **11th International Symposium on Applications of Ferroelectrics (ISAF XI)**.

I think it's no exaggeration to say that the Montreux ferroelectric event was a success. And that not only with respect to its scientific content but also to the overall ambiance at the triple conference. Maybe Professor Nava Setter, General Chair, gave us a clue when she said, "The spacious and comfortable Montreux Congress Center on the shores of Lake Geneva will ensure maximum benefit from the papers presented at the Conference. The extensive social program will provide enjoyable opportunities for interaction, discussion, and exchanges."

Interaction, discussion, and exchanges, aren't these some of the most vital ingredients ensuring a sustainable 21st century, let alone a better future in general?

This way of thinking and acting seems to be on the ascendancy. In the first circular announcing the **3rd Korea-Japan Conference on Ferroelectrics**, we read: "The primary goal is to bring together the scientists in both countries working in the field of ferroelectrics to exchange ideas and friendship and create the atmosphere of mutual cooperation."

We especially welcome participation of young students. The site of the Conference, Kyungju, was the capital of the Shilla dynasty, which unified the then divided Korea in 687 A.D. The Shilla dynasty influenced other ones which followed it, and its tradition still resides in the core of modern Korea. It will be an excellent opportunity to learn about Korean history."

With this in mind, we wish all of you the best of holidays, a time of reflection to prepare for the transition into the 21st century.

Rudolf Panholzer
Editor-in-Chief

IN THIS ISSUE

From the Editor	1
Conference Report	
Electroceramics VI	
ECAPD IV	
ISAF XI	2
Papers	
Electroceramics VI	
ECAPD IV	
ISAF XI	4
Upcoming Meetings	
FMA 16	35
3rd Korea-Japan Conf. on Ferroelectrics	35
Publications	
New volumes from MRS	37
Index of Volume 6	39
Calendar of Events	40

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CONFERENCE REPORT

THE MONTREUX FESTIVAL OF CONFERENCES

ELECTROCERAMICS VI

International Conference on Electroceramics and their Applications

ISAF XI

International Symposium on Applications of Ferroelectrics

ECAPD IV

European Conference on Applications of Polar Dielectrics

Montreux, Switzerland, 24-27 August 1998

Organized by the Laboratoire Ceramique of the EPFL in Lausanne headed by Prof. Nava Setter, a unique conference trilogy comprising the ELECTROCERAMICS VI (International Conference on Electroceramics and their Applications), the ISAF XI (International Symposium on Applications of Ferroelectrics), and the ECAPD IV (European Conference on Applications of Polar Dielectrics) has been held in Montreux, Switzerland, 24-27 August 1998.

As pointed out by Nava Setter during her introductory speech, two years before many members of our scientific community traveled to New Jersey, USA, then to Bled in Slovenia, and finally to Aveiro in Portugal to attend these three conferences in the period from middle of August to the first week of September 1996. The organizing committees of all three conferences agreed to have an exceptional joining of the three events this year in Montreux, at the Lake Geneva (Lac Lemman) in Switzerland. The meeting gathered 650 attendees (approximately 720 including the spouses), with the largest delegations from Japan, Germany, and the host country, followed by the USA, France, Great Britain, and with delegations from almost every other country in Europe, from Korea, China, India, Israel, Canada, Australia, and many other countries. The total number of presentations was 710, with 270 contributions for Electroceramics VI, 220 for ISAF XI, and another 220 for ECAPD IV.

A short look into the history of the three conferences shows that ELECTROCERAMICS I and II were initialized by the Belgian ceramic society and held as international conferences on electronic ceramics in Brussels in 1984 and 1988 respectively under the presidency of Prof. Duvinéaud. The third conference of this series was organized in Maubeuge, France, in 1992. Based on the success of this series and on the growing

number of participants, the Planning Committee decided in May 1992 to reduce the conference cycle time to two years. This led to the Electroceramics IV in Aachen, Germany, for which a doubling of the number of participants could be achieved over the previous event, and to the Electroceramics V in Aveiro, Portugal.

Ten years ago, in 1988, the first ECAPD and the ISAF have been held together in Zurich with 290 participants. The main topics have been ferroelectric domains and domain walls, pyroelectricity and pyroelectric sensors, piezoelectric actuators and sensors, relaxors, microwave dielectrics, electrooptic and photorefractive materials, as well as liquid crystals. There was only one paper directly referring to memories: "Large-scale use of ferroelectricity in microelectronics is reality" by E. G. Kostov and V. K. Malinovsky from the Siberian Branch of the Institute of Automation and Electrometry, Novosibirsk SBN—as seen from now, certainly a paper ten years ahead of its time.

The meeting in Montreux 1998 was preceded by an exciting summer workshop on the materials technology for ferroelectric microsensors and microactuators, organized by Paul Muralt at the EPFL (17-20 August) and by a tutorial program (21-22 August), organized by Bert Willig and Enrico Colla, covering the basics of ferroelectric and piezoelectric ceramics and thin films comprising contributions by Bob Newnham, Eric Cross, Sascha Tagantsev, Dragan Damjanovic, Marija Kosec, Paul Muralt, Rainer Waser, Angus Kingon, and Peter Günter.

The scientific program of the conference in Montreux comprised a series of plenary lectures highlighting research areas of strong current interest, three concurrent sessions of oral presentations every day, and three extended poster sessions. The plenary lectures covered the modeling of electroceramic materials and devices (R.

CONFERENCE REPORT

Waser), the present state and future of ferroelectric memories (C. Mazuré), the structure of grain boundaries in ceramics (M. Rühle), micromechanical devices as ultrasensitive sensors (J. K. Gimzewski), photovoltaic properties of mesoporous oxide films (M. Graetzel), and a broad view into the next century with its threats and hopes and the role which electroceramics might play in the future (B. Newnham).

The fields of the concurrent sessions have been grouped around DRAMs, FRAMs, size effects, pyroelectrics, thin film processing, ferroelectrics for microsystems, conductivity, interfaces, biomaterial and glass-ceramics, IR and microwave characterization, magnetic ceramics, nonlinear optics, microwave dielectrics, capacitors and packaging, piezoelectric actuators and sensors, domains, electromechanical effects, relaxors, ferroelectrics, as well as piezoelectrics for high frequencies. The participants profited from the fact that the topics of concurrent sessions were carefully selected to show the least overlap. The whole program proved to be excellently balanced. In addition, the local organizing committee of the EPFL together with the team of the Montreux Congress Center took great care to guarantee a smooth and satisfying running of the scientific meeting, the exhibition in the lobby of the conference center, and the spouses program.

The manuscripts for the three proceedings underwent a strict reviewing process during the conference. The proceedings of the Electroceramics VI papers will appear in the *Journal of the European Ceramic Society*, those of the ISAF XI will be appear in a special issue published by the IEEE according to their tradition, and the articles of the ECAPD IV will be published in *Ferroelectrics*.

The social program of the conference was absolutely

outstanding. It started on Sunday evening with a welcome reception (sponsored by Aixtron) at the Montreux Congress Center where we met many old friends again. It continued on the second evening with a lovely cable car ride into the mountains to an old castle in a huge park. We started in the rain but on the way the weather cleared up and, while eating snacks, we watched a wonderful sunset over Lac Lemman. Tuesday evening, in warm weather and without a cloud in the sky, we took off for a wheel boat trip passing the marvelous coastline halfway to Lausanne. After the return, we were served paella at the Conference Center during an extended poster session. Wednesday we had the Conference banquet at the Casino of Montreux, including an enjoyable magician show between the courses (raising many discussions among the participants on how the maiden disappeared from the box which the magician bristled with a dozen laser swords). During the dinner, Nava Setter announced the results of the committee meetings on the locations of the next events. Before final acceptance, the designated conference chairpersons of the next events had to pass an exam set up by the magician (and after some amusing initial problems, they all passed). Now we can look forward to the next Electroceramics in Slovenia, organized by Marija Kosec, the next ECAPD in Riga, Latvia, organized by A. Krumins, and the next ISAF in Hawaii, organized by Dwight Viehland and Angus Kingon.

The Montreux trilogy of conference concluded on Thursday evening with a farewell reception at the famous medieval Castle of Chillon, where we learned about the history of the region and we also learned to appreciate the wine of the region (if we did not already). In the name of all participants, I would like to express my thanks to Nava Setter and her wonderful team for a most charming and exciting event which we will always remember.

Rainer Waser
RWTH Aachen and FZ Jülich

Q: Where do we find the proceedings of the three conferences?

**A: Electroceramics VI in the *Journal of the European Ceramic Society*
ECAPD IV in the journal *Ferroelectrics*
ISAF XI as a Proceedings Volume (IEEE)**

MONTREUX PAPERS

PAPERS OF ELECTROCERAMICS VI '98, ECAPD IV '98, AND ISAF XI '98 DELIVERED 24-27 AUGUST 1998 IN MONTREUX, SWITZERLAND

In her message to the Montreux triple conference participants, General Chair Nava Setter said: "A large number of distinguished speakers from around the world have graciously accepted our invitation to present state-of-the-art findings in the science and engineering of electroceramics, ferroelectrics and polar dielectrics. The 700 contributions accepted for presentation in the meeting cover a large number of complementary topics, reflecting the breadth and depth of current activities in this interdisciplinary field. The balance between abstracts submitted from academic institutions and from industrial R&D laboratories is a testimony to the vitality of the field."

We are here listing the topics and authors of the papers, grouped according to fields. The proceedings of the three conferences will be published as follows:

*Electroceramics VI in the Journal of the European Ceramic Society
ECAPD IV in the journal Ferroelectrics
ISAF XI as a Proceedings Volume (IEEE)*

PLENARY SESSIONS

Modeling of electroceramics -
applications and perspectives.

R. Waser

Ferroelectric memories: present
state and challenges for the future.

C. Mazuré

Structure of grain boundaries in
ceramics.

M. Rühle

Micromechanical devices as ultra-
sensitive sensors.

J.K. Gimzewski

Optoelectronic properties of
mesoporous oxide films, the
nanocrystalline injection solar cell.

M. Graetzel

Electroceramics in the 21st Century.

R.E. Newnham

DRAMs

BSTO thin films for 1 Gbit DRAM
applications.

R. Laibowitz

Feasibility demonstration of a multi-
level thin film BST capacitor
technology.

*M. Watt, P. Woo, T. Rywak, L.
McNeil, A. Kassam, V. Joshi, J.
Cuchiario, and B. Melnick*

The influence of strain on the
dielectric behavior of (Ba,Sr)TiO₃
thin films deposited by LS-MOCVD
on Pt/SiO₂/Si.

*S.K. Streiffer, C.B. Parker, S.E.
Lash, and A.I. Kingon*

Control of the morphology of CSD-
prepared (Ba,Sr)TiO₃ thin films.

S. Hoffmann, and R. Waser

Dielectric and charge injection
properties of BST thin films for
capacitor application in DRAMs.

C.S. Hwang

Experimental evidence for space
charge limited ionic current trans-
ients in thin BST films.

*S. Zafar, R.E. Jones, B. Jiang, P.
Chu, B.E. White, D. Taylor, and
S. Gillespie*

Properties of BST thin films depos-
ited by photo-assisted MOCVD.

*W.W. Zhuang, Y.M. Chen, D.
Ritums, Q. Zhong, N.J. Wu, and
A. Ignatiev*

Dielectric properties of BaTiO₃-
SrTiO₃ artificially modulated
structure made by MBE.

*T. Tsurumi, T. Miyasou, Y.
Ishibashi, and N. Ohashi*

Dry-etching of barium-strontium-
titanate thin films.

*S. Schneider, T. Mono, B.
Albrethsen-Keck, Y. Melaku, and
R. Waser*

FRAMS

Ferroelectric capacitor technology
for nonvolatile FRAMS.

Y. Miyasaka

Polarization as a driving force in
accelerated retention measurements
on ferroelectric thin films.

S.D. Traynor

AFM studies on the domain orienta-
tion and piezoelectric activity

MONTREUX PAPERS

correlations in "as-prepared" and fatigued $\text{Pb}(\text{Zr,Ti})\text{O}_3$ thin film capacitors with Pt-electrodes.

E.L. Colla, D.V. Taylor, A.K. Tagantsev, and N. Setter

Effects of texture on fatigue rate of sol-gel PZT FECAPS with reactively sputtered RuO_2 electrode layers.

G. Norga, D. Wauters, A. Bartic, L. Fe, and H. Maes

Ferroelectric memories: problems and solutions

A.I. Kingon, S.K. Steiffer, S.H. Kim, and D. Thomas

Ferroelectric $\text{Sr}_x\text{Bi}_{2-x}\text{Ta}_2\text{O}_9$ thin films deposited by MOCVD.

J.F. Roeder, B.C. Hendrix, F. Hintermaier, D.A. Desrochers, G. Bhandari, M. Chappuis, T.H. Baum, P.C. Van Buskirk, C. Dehm, E. Fritsch, N. Nagel, W. Hohnlein, and C. Mazuré

Properties of $\text{Sr}_2\text{Nb}_2\text{O}_7$ family ferroelectric thin films.

Y. Fujimori, N. Izimi, T. Nakamura, and A. Kamisawa

Structural and electrical properties of metal-ferroelectric-silicon heterostructure made by direct wafer bonding and layer transfer process.

M. Alexe, A. Pignolet, D. Hesse, and U. Gösele

CONDUCTIVITY

SOFC in dispersed power generation.

W. Drenckhaan

Protonic conduction in $\text{Ba}_3\text{Ca}_{1.18}\text{Nb}_{1.82}\text{O}_{9-d}$

H.G. Bohn, and T. Schober

Electrical characterisation of thin cathode-layer for SOFC.

D. Herbstritt, T. Egner, A. Krügel, and E. Ivers-Tifée

New cathodes in the $\text{Li}_x\text{Al}_y\text{M}_{1-y}\text{O}_2$ (M=Co, Mn) system for rechargeable lithium batteries.

Y.M. Chiang, G. Ceder, D.S. Sadoway, Y.I. Jang, B. Huang, and H. Wang

The effect of cation place exchange on the electrical conductivity of $\text{SrBi}_2\text{M}_2\text{O}_9$ (M=Ta, Nb).

D.M. Smyth, and A.C. Palanduz

Electrical conductivity and nonstoichiometry in doped $\text{Sr}_3\text{Ti}_2\text{O}_7$.

H.L. Tuller, C. Navas, and H.C. Zur Loye

Low temperature defect chemistry of oxides: general relations and case studies.

K. Sasaki, and J. Maier

Contribution to the knowledge of electrical mechanisms in tin dioxide gas sensors by physical and quasi-chemical study of point defects.

L. Poupon, P. Lacconi, and C. Pijolat

Processes leading to superconducting ceramic/metal composite tapes for industrial use.

R. Flükiger

Electrical humidity response of sol-gel processed undoped and alkali-doped $\text{TiO}_2\text{-Al}_2\text{O}_3$ thin films.

P. Innocenzi, A. Bearzotti, E. Traversa, and G. Gusmano

High-load-resistors based on doped

titanate ceramics showing an overall PTCR-behavior.

R. Moos, M. Fandel, and W. Schäfer

On linear resistivity from -1 to 103K in $\text{Sr}_2\text{RuO}_{4-d}$ single crystals grown by flux technique.

D. Pavuna, H. Berger, and L. Forro

BIOMATERIALS & GLASS-CERAMICS

Piezoelectricity, pyroelectricity, and ferroelectricity in biomaterials: a review of recent results and some speculation on their biological significance.

S.B. Lang

Decrystallisation of glass ceramics under ion exchange diffusion.

D.K. Tagantsev, and Yu. G. Korolyov

Formation and growth of semiconductor nanocrystals in phosphate glass matrix.

A.A. Lipovskii, I.E. Jakovlev, E.V. Kolobkova and V. Petrikov

Preparation and electrical properties of sol-gel derived lead zirconate titanate glass-ceramic thin films.

K. Saegusa

PIEZOELECTRIC ACTUATORS

Mecatronic using piezoelectric actuators.

P. Jänker

Commercial applications

MONTREUX PAPERS

of passive and active piezoelectric vibration control.

S. Yoshikawa

Smart structures by integrated piezoelectric thin fibers (I): preparations properties and integration of piezoelectric fibers in the system $\text{Pb}(\text{Zr,Ti})\text{O}_3$.

D. Sporn, W. Watzka, K. Pannkoke, and A. Schönecker

Development of tube actuators by solid freeform fabrication.

A.M. Umarji, B Garibagaoglu, A.L. Kholkin, S.C. Danforth, and A Safari

Solid freeform fabrication of novel piezoelectric ceramics and composites for sensor and actuator applications.

A. Safari, and S.C. Danforth

Interaction between electrodes and ceramics in multilayer PZT.

K. Lubitz, H. Bödingen, and C. Schuh

Novel piezoelectric structures for sensor and actuator applications.

J.E. Holmes, D.H. Pearce, T.W. Button, R. Wytt, and R. Fernihough

Characterization of piezoceramic under uniaxial stress.

D. Guyomar, D. Audigier, and L. Eyraud

Relaxor-PT single crystal piezoelectric for high performance actuators and transducers.

T.R. Shrout, S.-E. Park, P.D. Lopath, and K.K. Shung

Growth of large and homogeneous PZN-PT single crystals for medical ultrasonics array transducers.

T. Kobayashi, S. Saitoh, K. Harada, S. Shimanuki, and Y. Yamashita

Piezoelectric properties and phase transitions of $\text{PbNi}_{1/3}\text{Nb}_{2/3}\text{O}_3$ - PbTiO_3 - PbZrO_3 ceramics.

M. Kondo, M. Hida, M. Tsukada, K. Kuniyama, M. Kutami, and H. Kamehara

Lead based perovskite materials for high strain actuation.

C. Heremans, and H.L. Tuller

Dielectric and piezoelectric properties of $\text{Pb}(\text{Sc}_{1/2}\text{Nb}_{1/2})\text{O}_3$ - $\text{Pb}(\text{Ni}_{1/3}\text{Nb}_{2/3})\text{O}_3$ - PbTiO_3 ternary ceramic materials.

N. Ichinose, S. Natsume, and Y. Yamashita

BULK CERAMIC PROCESSING

High Performance ferroelectric thick films.

M. Kosec

Smart structures by integrated piezoelectric thin fibers (II): properties of composites and their theoretical description.

A Schönecker, U. Keitel, W.S. Kreher, D. Sporn, and W. Watzka

Formation and physical properties of piezoelectric thick film produced by gas-deposition method.

M. Ichiki, J. Akedo, A. Schroth, Y. Morikawa, R. Maeda, and Y. Ishikawa

Led-free piezoelectric ceramics of $(\text{Bi}_{1/2}\text{Na}_{1/2})\text{TiO}_3$ - KNbO_3 -1/

2. $(\text{Bi}_2\text{O}_3\cdot\text{Sc}_2\text{O}_3)$ system.

T. Takenaka, and H. Nagata

SIZE EFFECTS

Nano-phase ferroelectric devices.

J.F. Scott

Polarization phenomena in ferroelectric thin films at the nanometer scale.

A. Gruverman, S.A. Prakash, S. Aggarwal, R. Ramesh, O. Auciello, and H. Tokumoto

Nanometer control of the ferroelectric polarization in atomically smooth $\text{Pb}(\text{Zr}_{0.2}\text{Ti}_{0.8})\text{O}_3$ thin films.

T. Tybell, C.H. Ahn, M. Foeth, P. Stadelmann, and J.-M. Triscone

Scaling and interfacial effects in ferroelectric materials.

C.A. Randall, X. Liu, D. McCauley, and T.R. Shrout

Ultra thin oriented PVDF films.

V. Fridkin

Ferroelectricity in ultra thin epitaxial $\text{Pb}(\text{Zr}_{0.2}\text{Ti}_{0.8})\text{O}_3$ films.

C.H. Ahn, T. Tybell, and J.-M. Triscone

Electrical properties of thin MOCVD PZT.

S. Bilodeau, S. Johnston, M. Russell, and P. Van Buskirk

Structure-property relations in mesoscopic BaTiO_3 and PbTiO_3 ferroelectrics.

K. Akdogan, W. Mayo, A. Safan, E.A. Payzant, W.D. Porter, C.J. Rawn, and C.R. Hubbard

MONTREUX PAPERS

INTERFACES

Mass and charge transport involving interfaces.

J. Maier

Detailed temperature dependence of the space charged layer width grain boundaries in acceptor-doped SrTiO_3 ceramics.

R. Hagenbeck, and R. Waser

High temperature transport properties at metal/ SrTiO_3 interface.

T. Kawada, N. Iizawa, M. Tomida, T. Watanabe, A. Kaimai, K. Kawamura, Y. Nigara, and J. Mizusaki

On the validity and limits of the brick layer model in impedance spectroscopy.

J. Fleig, and J. Maier

Experimental and theoretical studies of nonlinear charge transport phenomena in ferroelectric ceramics.

I. Raevski, A.N. Pavlov, M.A. Malitskaya, A.S. Bogatin, and P.F. Tarasenko

Interfacial chemistry and intergranular films in electroceramics.

Y.-M. Chian, D.A. Blom, H. Wang, and J. Luo

Restructuring the surface region of donor doped SrTiO_3 single crystals under oxidizing conditions.

R. Meyer, K. Szot, and R. Waser

The influence of grain boundaries on ionic conductivity in YSZ.

C.A.J. Fisher, and H. Matsubara

Coupled properties of polarizable semi-conductors.

M. Maglione, T. Salva, and

J. Mangin

Influence of $\text{Bi}_2\text{O}_3/\text{TiO}_2$, Sb_2O_3 and Cr_2O_3 doping on microstructural and electrical characteristics of ZnO based varistor ceramics.

S. Bernik, P. Zupancic, and D. Kolar

INFRARED & MICROWAVE CHARACTERISATION

Infrared and microwave dielectric response of the disordered antiferroelectric $\text{Ag}(\text{Nb}, \text{Ta})\text{O}_3$ system.

J. Petzelt, E. Buixaderas, S. Kamba, J. Pokorny, J. Polivka, V. Koukal, A. Kania, G.A. Komandin, A.A. Volkov, and V. Bovtoun

Extrinsic loss mechanisms in $\text{BaMg}_{1/3}\text{Ta}_{2/3}\text{O}_3$ and $\text{BaO-Re}_2\text{O}_3\text{-TiO}_2$ ceramics.

C. Zuccaro, C. Hoffmann, M. Winter, N. Klein, and R. Waser

A Raman scattering study of lead titanate thin film on MgO substrate.

R. Farhi, Y.I. Yusyuk, V.L. Lorman, and E.V. Sviridov

Dielectric response of various PLZT ceramics in the range $10^2\text{-}10^{14}$ Hz and 10-550K.

S. Kamba, J. Petzelt, J. Polivka, J. Endal, J. Banys, R. Mizaras, A. Brillings, and M. Kosec

PIEZOELECTRIC SENSORS

Current status and future trends in ultrasonic transducers for medical imaging applications.

T.R. Gururaja

Ferroelectric ceramics and composites: statistical models for effective piezoelectric and pyroelectric properties.

W.S. Kreher, and J. Rödel

Propagation of lamb waves in 1-3 piezocomposite and its application to liquid sensors.

F. Teston, G. Feuillard, D. Certon, F. Levassort, and M. Lethiecq

Separate poling of inclusions and matrix in PT/P(VDF-TrFE) 0-3 composites.

B. Ploss, F.G. Shin, H.L.W. Chan, and C.L. Choy

Energy trapping phenomenon of piezoelectric $\text{SrBi}_2\text{Nb}_2\text{O}_9$ ceramics.

A. Ando, M. Kimura, and Y. Sakabe

DOMAINS

Balance of intrinsic and domain related responses in some practical ferroelectric systems.

L.E. Cross

Universal nonlinear behavior of soft PZT-piezoceramics.

V. Müller, and Q.M. Zhang

Extrinsic piezoelectric and dielectric response in ferroelectric ceramics and thin films.

D. Damjanovic

Domain wall processes and piezoelectric properties of ceramic ferroelectrics.

A.V. Turik

Ferroic microstructures - their origin

MONTREUX PAPERS

and time evolution.

E.K.H. Salje

Domain engineering: Periodic domain patterning in lithium niobate.

V.Y. Shur, E.L. Rumyantsev, R.G. Batchko, G.D. Miller, M.M. Fejer, and R.L. Byer

Influence of defects and conductivity on the phase transitions and the domain structure properties in ferroelectric-semiconductors $\text{Sn}_2\text{P}_2\text{S}(\text{Se})_6$.

Y. Vysochanskii, A. Molnar, and M. Khoma

Direct observation of potential distribution across ferroelectric capacitor using off-axis electron holography.

K. Honda

Scanning nonlinear dielectric microscope with submicron resolution.

Y. Cho, and K. Yamanouchi

PYROELECTRICS

Sputtering of self-polarized PZT films for IR-detector arrays.

R. Bruchhaus, D. Pitzer, M. Schreiter, and W. Wersing

Pyroelectric properties of oriented $\text{MOD Bi}_3\text{Ti}_4\text{O}_{12}$ and PZT films for sensor applications.

R.C. Buchanan

The spatial distribution of polarization and space charge in sputtered PZT thin films.

G. Suchaneck, T. Sandner, R. Köhler, P. Padmini, G. Gerlach, V.P. Afanasjev, and

E.A. Tarakanov

Pyroelectric response of LiTaO_3 thin film on silicon dioxide membrane.

C.H. Kohli, P.E. Schmid, and F. Lévy

Gas spectrometry based on a pyroelectric thin film array.

B. Willing, P. Muralt, N. Setter, and O. Oehler

THIN FILM PROCESSING

Microsystems, nanotechnology and ferroelectrics.

R. Whatmore

Effect of the precursor type on crystallization and microstructure of PbTiO_3 and $\text{Pb}(\text{Zr,Ti})\text{O}_3$ thin films.

B. Malic, M. Kosec, K. Smolej, and S. Stavber

Preparation and electrical properties of sol-gel derived antiferroelectric $\text{Pb}_{0.99}[(\text{Zr}_{0.6}\text{Sn}_{0.4})_{0.96}\text{Ti}_{0.04}]_{0.98}\text{Nb}_{0.02}\text{O}_3$ thin films.

J.H. Jang, K.H. Yoon, and K.Y. Oh

Relationship between processing and electrical behavior of BST films deposited by spin coating.

E. Dien, M. Lejeune, and A. Smith

In situ fabrication SrTiO_3 - BaTiO_3 layered thin films by hydrothermal-electrochemical technique.

M. Yoshimura, W. Suchanek, T. Watanabe, and B. Sakurai

Electrophoretic deposition and sintering of thin/thick films of lead based electroceramics.

J. Van Tassel, and C.A. Randall

Synthesis of oriented meso-structure silica functional thin film.

H.S. Zhou, D. Kundu, and I. Honma

Preparation and electrical properties of barium titanate film and strontium titanate film by hydrothermal method.

C.-F. Kao, and C.-L. Yang

Epitaxial bilayered perovskite ferroelectric thin film heterostructures by large area pulsed laser deposition.

A. Pignolet, C. Curran, M. Alexe, S. Senz, and D. Hesse

Structural and electrical properties of epitaxial SBT thin films.

L.-R. Zheng, S. Mangenot, S.-M. Koo, and K.V. Rao

An investigation of vacancy related defects in $(\text{Pb,L a})(\text{Zr,Ti})\text{O}_3$ capacitors using positron annihilation.

T. Friessnegg, S. Madhukar, S. Aggarwal, R. Ramesh, B. Nielsen, D.J. Keeble, and E.H. Poindexter

Influence of the deposition parameters controlled by OES on PZT thin film properties deposited by rf magnetron sputtering.

F. Ayguavives, B. Ea-Kim, P. Aubert, and B. Agius

MAGNETIC CERAMICS

Growth and properties of magnetoresistive oxide films: progress towards low field magnetoelectronics.

R. Ramesh, S.B. Ogale, M.

MONTREUX PAPERS

Rajeswari, R.L. Greene, and T. Venkatesan

Influence of oxygen stoichiometry on electrical transport and magnetic properties of doped perovskite-type ferrate and manganate single crystals.

T. Maeder, and J.G. Bednorz

Magnetotransport property of layered manganate $(\text{La,Sr,Ca})_3\text{Mn}_2\text{O}_7$.

M. Takemoto, A. Katada, T. Ogawa, and H. Ikawa

Transverse and longitudinal magnetoresistance of $\text{La}_{0.7}(\text{Ca,Sr})_{0.3}\text{MnO}_3$ thin films, prepared by chemical solution deposition (CSD).

C. Mitze, U. Hasenkox, R.R. Arons, and R. Waser

NONLINEAR OPTICS

Novel highly nonlinear optic inorganic and polymer crystals.

P. Günter

Side chain polar polymers: properties and applications.

J.-C. Dubois

Highly polar molecular crystals for electrooptic applications.

I. Liakatas, M.S. Wong, Ch. Bosshard, and P. Günter

Ferroelectricity driven holographic properties of $\text{Sr}_{1-x}\text{Ba}_x\text{Nb}_2\text{O}_6$ crystals.

T. Volk, Th. Woike, U. Doerfler, R. Pankrath, M. Woehlecke, and L. Ivleva

Quantum structures based on ZnO towards ultraviolet laser diodes.

M. Kawasaki, A. Ohtomo, R. Shiroki, H. Kimura, I. Ohkubo,

H. Koinuma, T. Yasuda, and Y. Segawa

ELECTROMECHANICAL EFFECTS

Fracture mechanics of ferroelectric ceramics - influence of the electric field.

G.A. Schneider

Correlation between electromechanical stress and domain wall mobility of hard and soft piezoelectric PZT ceramics containing different Zr/Ti-ratios.

M. Hammer, A. Endriss, M.J. Hoffmann, A. Kolleck, and G.A. Schneider

Fracture of PZT ceramics under mechanical/electrical load.

R. Fu, and T.-Y. Zhang

R-curve behavior of BaTiO_3 and PZT caused by domain switching.

A. Kolleck, G.A. Schneider, and F. Meschke

FERROELECTRICS FOR MICROSYSTEMS

Materials issues in ferroelectric thin films for MEMS.

P. Muralt

Direct-write fabrication of integrated, multilayer ceramic devices.

D. Dimos, P. Yang, B.H. King, T.J. Garina, S.L. Morissette, and M.A. Rodriguez

Phase development and electrical and piezoelectric characterization of epitaxial $\text{Pb}_{1-x}\text{Ba}_x(\text{Mg}_{1/3}\text{Nb}_{2/3})\text{O}_3$ -

PbTiO_3 thin films.

J.-P. Maria, E.A. Payzant, J.F. Shepard Jr., and S. Trolier-McKinstry

Characterization of PLZT ceramics for printing elements.

A. Levstik

Ferroelectric PZT thin films on steel substrates: preparation and application as sensor elements.

S. Seifert, M. Giersbach, P. Löbmann, D. Sporn, T. Hauke, and H. Beige

MICROWAVE DIELECTRICS

Chemical domain growth in PMN-type relaxors and perovskite microwave dielectrics.

P.K. Davies, and M.A. Akbas

The role and the site occupancy of rare earth dopants in BaTiO_3 capacitor ceramics.

A. Hitomi, S. Cheng, H. Sommariva, and C.A. Randall

Integrated passive components using low temperature cofired ceramics.

W. Wersing, S. Gohlke, and W. Eurskens

A novel phased array antenna that uses ferroelectrics and bulk phase shifting.

J.B.L. Rao, and D.P. Patel

Microwave quality factor improved by ordering of Ba and rare-earth on the tungstenbronze-type

$\text{Ba}_{6.3x}\text{R}_{8+2x}\text{Ti}_{18}\text{O}_{54}$ ($\text{R}=\text{La, Pr, Nd, Sm}$) solid solutions.

H. Ohsato, M. Imaeda, A. Komura, Y. Takagi, S. Nishigaki,

MONTREUX PAPERS

and T. Okuda

CAPACITORS AND PACKAGING

Ceramics for ultra thin dielectric layer of multilayer ceramic capacitors.

Y. Sakabe

Influence of the thickness of dielectrics on the electrical properties for multilayer ceramic capacitor with Ni electrode.

H. Chazono, Y. Inomata, and H. Kishi

Mechanism of improvement of resistance degradation in Y-doped BaTiO₃ based MLCCs with Ni electrodes under highly accelerated life testing.

S. Sato, Y. Nakano, A. Sato, and T. Nomura

Hermetic glass sealing of ALN packages for high temperature applications.

R. Krüger, A. Roosen, and W. Schaper

RELAXORS

Dipolar glasses.

R. Böhmer

Relaxor ferroelectric polymers.

Q. Zhang, and V. Bharti

Dielectric nonlinearity in SrTiO₃:Ba.

V.V. Lemanov, A.V. Sotnikov, E.P. Smirnova, M. Weihnacht, and R. Kunze

Electric field induced phase transition in relaxor ferroelectrics-lead magno-niobate and lead zinconibate.

L.S. Kamzina, and N.N. Krainik

Light scattering and phase transition dynamics in PMN.

I.G. Siny, and R.S. Katiyar

FERROELECTRICS

Equilibrium states and phase transitions in epitaxial ferroelectric thin films.

N.A. Pertsev, A.G. Zembilgotov, and A.K. Tagantsev

Translational vibrations of domain boundaries in ferroelectrics with different defect concentration.

A.S. Sidorkin, and A.S. Sigov

High intensity electron emission from ferroelectrics - a review.

H. Gundel

Ferroelectric behaviors dominated by randomly quenched and mobile impurities in PZT.

D. Viehland, Q. Tan, and J.-F. Li

PIEZOELECTRICS FOR HIGH FREQUENCIES

Growth of new langasite single crystals for piezoelectric applications.

T. Fukuda, H. Takeda, K. Shimamura, H. Kawanaka, M. Kumatoriya, S. Murakami, J. Sato, and M. Sato

Orientation and spontaneous polarization of LiNbO₃ films prepared by bias sputtering.

T. Shiosaki, and T. Nishida

Influence of interstitial oxygen on the c-axis orientation of sputtered and e-beam evaporated ZnO thin films.

V. Gupta, K. Sreenivas, and M. Fahim

Aluminum nitride thin films for high frequency applications.

M.-A. Dubois, and P. Muralt

POSTER PRESENTATIONS

CONDUCTIVITY, SOFC, CHARGE TRANSPORT, GRAIN BOUNDARIES, DIFFUSION...

Electrical conductivity of Sr_{1-x}Ti_{1-y}Nb_yO_{3+d} materials.

J.C.C. Abrantes, J.A. Labrincha, and J.R. Frade

Structure and electrical behavior in air of TiO₂-doped stabilized tetragonal zirconia ceramics.

F. Capel, C. Moure, P. Duran, A.R. Gonzalez-Elipe, and A. Caballero

Effects of humidity on the electrical behavior of Sr_{0.97}Ti_{1-x}FexO_{3-d}.

J.R. Frade, M.E. Costa, J.R. Jurado, and M.T. Colomer

Oxygen losses and electrical conductivity of SrTi_{1-y}Nb_yO_{3+d}.

A.A.L. Ferreira, J.C.C. Abrantes, J.A. Labrincha, and J.R. Frade

Modelling of stoichiometry polarization of bulk and grain boundaries in electroceramics.

J. Jamnik, and J. Maier

STM/STS studies of single crystal-

MONTREUX PAPERS

line metaloxide/ferroelectric heterostructures.

O. Kuffer, Ch. Renner, L. Antognazza, T. Tybell, J.M. Triscone, and O. Fischer

Synthesis of LiCoO₂ with uniform grain size distribution.

T. Nakamura, and A. Kajiyama

Photoconductive properties of Bi₄Ti₃O₁₂ film.

L. Pintilie, I. Pintilie, and M. Alexe

Sintering and electrical properties of doped lanthanum gallate.

A. Ringuede, M.C. Steil, and J. Guindet

New Experimental approaches to characterize silicon carbide hot rods.

P.-O. Robert, and J. Fouletier

Impedance spectroscopy analysis of Pb₅Al₃F₁₉.

J.M. Reau, A. Simon, M. El Omari, and J. Ravez

Dielectric ceramic based on ZrO₂ for humidity sensors.

I.B. Vynnyk

Application for lithium secondary battery of superionic conductors Li_{3-2x}(In_{1-x}Zr_x)₂(PO₄)₃ (0 ≤ x ≤ 0.2).

K. Yoshikawa, T. Suzuki, N. Hayakawa, K. Uematsu, K. Toda, and M. Sato

Electrical and electrochemical characterization of bulk and layers of LaNiO₃ ceramic perovskites.

M.T. Colomer, A. Martinez, C. Pascual, and J.R. Jurado

Electronic noses, a different ap-

proach to the sensitivity and selectivity issues.

P.M Faia, M.A. Pereira, A.M. Nunes and C.S. Furtado

Detection mechanism and time response to TiO₂-based ceramic H₂ sensors.

G.C. Mather

Preparation of PTCR ceramics in the BaO-Nb₂O₅-TiO₂ system.

I. Zajc, and M. Drofenik

Stability of calcium substituted lanthanum chromites used as SOFC anodes for methane oxidation.

J. Sfeir, J.V. Herle, and A.J. McEvoy

The hop-and-return conductivity mechanism in hydrogen bound ferroelectrics via microwave spectra.

G.I. Ovtchinnikova, A.V. Sapronova, and A.N. Soloshenko

Impedance spectroscopy of n-doped (Ba, Sr)TiO₃ ceramics prepared by the modified low temperature aqueous synthesis.

M. Viviani, P. Nanni, M.T. Buscaglia, M. Leoni, V. Buscaglia, and L. Centurioni

Humidity sensitive electrical properties of a novel ceramic heterocontact structure ZnO/BaPb_{0.8}Bi_{0.2}O₃.

A. Glot, E. Di Bartolomeo, and E. Traversa

Gas sensing properties of platinum-dispersed TiO₂ thin film derived from precursor.

I. Hayakawa, Y. Iwamoto, K.-I. Kikuta, and S.-I. Hirano

Characterization of Zn₃(VO₄)₃ phases in V₂O₅-based ZnO varistors.

H.H. Hng, and K.M. Knowles

Ba₃(CaNb₂)O₉ ceramics: the effect of acceptor and donor dopants on the formation and mobility of electronic and protonic defects.

F. Allmendinger, K.D. Kreuer, T. He, and J. Maier

Photoconductivity of SBT thin films.

L. Pintilie, and M. Alexe

Direct measurements of voltage-current characteristics of single grain boundary of ZnO varistors.

S. Tanaka, and K. takahashi

Electrochemical permeability of LaCoO₃-based electrode materials.

F.M. Figueiredo, F.M.B. Marques, and J.R. Frade

PTCR behavior of highly donor doped BaTiO₃.

S. Urek, and M. Drofenik

Concepts for the simulation of the impact of internal boundaries on the long range charge transport in acceptor-doped titanates.

T. Hölbling, and R. Waser

Ion exchange properties of NASICON-type ceramics - application to ion selective electrodes.

F. Mauvy, and E. Siebert

Ionic/electronic mixed conduction relations in perovskite-type oxides modified by the defect structure.

H. Ullmann, N. Trofimenko, D. Stöver, and A. Naoumidis

MONTREUX PAPERS

Measurements of conductivity profiles in acceptor-doped strontium titanate.

S. Rodewald, J. Fleig, and J. Maier

Mixed ionic and electronic conduction in Mn/Mo doped gadolinium titanate.

H.L. Tuller, and J.J. Sprague

P-type conductivity of gadolinia doped ceria.

F.M. Figueiredo

Sublinear voltage-current relationship in small grain oxide ceramics.

A.B. Glot, and A.N. Bondarchuk

Proton conductivity in BaTb_{0.6i}In_{0.4O(2.8+y)}Hy, a new compound with the simple perovskite-like structure.

R.R. Arons

Vacuum plasma spray processing and electrochemical behavior of LSM-YSZ composites cathodes.

S. Rambert, A.J. McEvoy, and K. Barthel

BICOVOX: sintering and grain size dependence of the electrical properties.

M.C. Steil, J. Fouletier, M. Kleitz, and P. Labrune

Electrical conductivity of strontium bismuth titanate under controlled oxygen partial pressure.

C. Voisard, D. Damjanovic, and N. Setter

Structure and conducting properties of La_{1-x}Sr_xCoO_{3-d}.

X. Chen, N.J. Wu, and A. Ignatiev

Electrical conductivity of ceramic materials on the base of manganese-containing spinels.

I. Hadzaman, M. Kravtsiv, A. Kovalskiy, O. Mrooz, O. Shpotyuk, and M. Vakiv

Scanning tunneling microscopy and spectroscopy of semiconducting BaTiO₃ ceramic.

T. Kolodiazhnyi, and D.F. Thomas

Structure, composition and electrical properties of thin-films of the mixed ionic-electronic conductor CuBr.

P. Lauque, C. Jocolin, J.-L. Seguin, M. Pasquinelli, and P. Knauth

NMR study of sol-gel processed NASICON.

S. Lioccia, M.L. Di Vona, E. Traversa, and L. Montanaro

Preparation and characterization of La_{Nix}Co_{1-x}O₃ thin films on polycrystalline Al₂O₃-substrates.

B. Trummer, O. Fruhwirth, K. Reichmann, M. Holzinger, W. Sitte, and P. Pölt

Acoustic emission studies of PTCR ceramics.

E.A. Dul'kin, and I.P. Raevski

Preparation and characterization of transition metal brownmillerites using *in situ* diffraction.

S.A. Speakman, and S.T. Misture

Non-stoichiometry and relaxation kinetics of nanocrystalline mixed praseodymium-cerium oxide Pr_{0.7}Ce_{0.3}O_{2-x}.

H.L. Tuller, and P. Knauth

Multiple lanthanide doping of solid electrolytes; AC conductivity behavior.

J. Van Herle, D. Seneviratne, and A.J. McEvoy

Electrochemical promotion of ruthenium oxide catalysts for gas phase combustion of ethylene.

S. Wodiunig, and C. Comninellis

Electrochemical characterization of oxygen exchange and transport in electronically conducting cobaltates.

A. Closset, S. Diethelm, K. Nisancioglu, J. Van Herle, and A.J. McEvoy

Structural and electrical characterization of silica-containing yttria-stabilized zirconia.

C.C. Appel, and N. Bonanos

Peculiarities of PTC thermistor formation in the case of the partial substitution of titanium ions by aliovalent ions.

O.I. V'Yunov, and A.G. Belous

A pulsed method for measuring the total ionic conductivity on solid state ionic conductors.

J. Certo, C.S. Furtado, A. J. Ferreira, and J.M. Perdigo

Structure/property relations in negative temperature coefficient thermistors.

G. Csete de Györgyfalva, I.M. Reaney, and A. Nolte

Coupling between the atomistic structure and chemical composition of grain boundaries in Fe-doped strontium titanate.

O. Kienzle, F. Ernst, and M. Rühle

MONTREUX PAPERS

PHOTOVOLTAICS

Effect of multiple impurity doping on the photovoltaic properties of lead zirconate-titanate ceramics.

K. Nonaka, M. Akyama, T. Hagio, and A. Takase

Effect of Pb/(Zr+Ti) molar ratio on the photovoltaic properties of lead zirconate-titanate ceramics.

K. Nonaka, M. Akyama, T. Hagio, and A. Takase

OPTICAL MATERIALS, PROPERTIES AND DEVICES

Comparison of optical and electrical characteristics of SnO₂:F thin films electrodes deposited by pyrosol from either tin tetrachloride or dibutyltindiacetate base solutions.

E. Dien, J.M. Laurent, and A. Smith

Crystal chemistry of new luminescent materials containing pentavalent cation.

S. Tobitsuka, T. Honma, T. Wakayama, K. Toda, and M. Sato

Preparation and optical properties of PbS/or mosils quantum dot nanocomposites.

X.-P. Zou, L.Y. Zhang, X. Yao, L.-K. Wang, and F.-X. Zhang

Electro-optical control systems of piezotransformers.

A.A. Yerofeyev, and S.A. Yerofeyev

Influence of the non-stoichiometry on the electrooptic properties in pure LiNbO₃.

M. Aillerie, M.D. Fontana, F.

Abdi, K. Chah, P. Bourson, K. Polgar, and G. Malovichko

Stoichiometric LiTaO₃ for ultraviolet photorefractive.

P. Bernasconi, G. Montemezzani, P. Günter, Y. Furukawa, and K. Kitamura

Experimental study of the behavior of narrow nanosecond laser pulses in biased photorefractive Bi₁₂TiO₂₀.

D. Wolfersberger, N. Fressengeas, J. Maufroy, and G. Kugel

Optical study on the ferroelectric transition in PbHPO₄.

N. Ohno, and N. Kida

Optical wave guides from sputtered BaTiO₃ thin films.

A. Dazzi, A. Gueldry, P. Sibillot, P. Mathey, P. Julien, and M. Maglione

PZT thin film deposition and determination of their optical properties.

M.J.M. Gomes, M. Vasilevsky, D. Czekaj, and M. Pereira

Electrooptical analogs of piezotransducers.

A.A. Yerofeyev, and S.A. Yerofeyev

Optical characterization of charge-transport in polar dielectrics.

I. Baggio, and P. Günter

Polymer based electrooptic in-line fiber modulator.

M. Bösch, I. Liakatas, M. Jäger, Ch. Bosshard, and P. Günter

Growth and properties of tungsten-

bronze ferroelectric potassium lithium niobate single crystals.

T. Karaki, K. Miyashita, M. Nakatsuji, M. Adachi, and A. Kawabata

Evaluation of electrooptic coefficients of (Pb,Lu)TiO₃ thin films.

E. Dogheche, D. Remiens, A. Boudrioua, and J.C. Loulergue

Optical and electrooptical properties of hydrogen-bonded selenates.

L. Guilbert, P. Kolata, J.P. Salvestrini, and M. Fontana

High temperature optical absorption spectroscopy of doped and undoped BaCeO₃.

H. Huck, P. Ehrhardt, and W. Schilling

PZT coated optical fibers for acousto-optical modulation.

J. Eitle, G. Fox, P. Mural, and N. Setter

Electrooptic properties of Sn₂P₂S₆.

J. Kroupa, Y.I. Tyagur, A.A. Grabar, and Y.M. Vysochanskii

Near infrared photorefractive in reduced Rh-doped KNbO₃.

C. Medrano, M. Ewart, I. Biaggio, R. Ryf, and P. Günter

Photorefractive Ce doped KNbO₃ as holographic storage material.

R. Ryf, G. Montemezzani, and P. Günter

Surface characteristics of photostrictive actuator in PLZT ceramics.

P. Poosanaas, A. Dogan, S. Thakoor, and K. Uchino

MONTREUX PAPERS

Criteria for the research of new materials for opto-mechanical devices.

R. von der Mühl, J. Ravez, J.P. Doumerc, and A. Simon

Optical and structural characterization of zinc vapor diffused waveguides in lithium niobate crystals.

A. Vyacheslav, A. Fedorov, Y.N. Korishko, G. Lifante, and F. Cusso

PYROELECTRICS, INFRARED SENSING, POLARIZATION

Pyroelectric properties of the multi-component ferroelectric ceramic materials.

D. Czekaj, M.F. Kuprianov, and Yu.N. Zakharov

Poling distribution and temperature.

J. de Frutos, A.M. Gonzalez, C. Duro, and M.J. Melcon

Pyroelectric characterization of spin coated corona charged P(VDF/TrFE) copolymer films.

S.L. Bravina, N.V. Morozovsky, Z. Xia, J. Song, G. Chen, and Y. Zhang

Plane- and cavity-shaped polymer film pyroelectric sensors of radiation.

S.L. Bravina, N.V. Morozovsky, J. Kulek, and B. Hilczer

Pyroelectric breakdown and its application.

J. Kulek, S.L. Bravina, N.V. Morozovsky, and B. Hilczer

Selective pyroelectric response of dye-doped PVDF.

B. Hilczer, J. Kulek, and H. Smogor

Thermophysical control of pyroelectric materials.

V. Zavorotny, L. Pasechnik, and Y. Yakimenko

Low-temperature pyroelectricity.

V.K. Novik, N.D. Gavrilova, and I.A. Malyshkina

The pulse electron emission and local changes of pyroelectric potential in lithium niobate crystals.

L.S. Kokhanchik, and E.B. Yakimov

The polymer defects and the phase transitions in pyroelectrics.

A.F. Klinskikh

Pyroelectric and dielectrics properties of the ceramics on lead ferroniobate base.

L.E. Pustovaya, Y.N. Zakharov, I.P. Raevskii, E.I. Eknadiosiants, A.N. Pinskaya, V.A. Babanskikh, V.Z. Borodin, and S.M. Golubkin

Polarization distribution effect on the pyrocurrent frequency dependence during heat flux modulation.

A.A. Bogomolov, and O.V. Malyshkina

RF-sputtered PZT thin films for infrared sensor arrays.

R. Köhler, P. Padmini, G. Gerlach, G. Suchanec, T. Sandner, and G. Hofmann

Multi-element uncooled sensors based on organic pyroelectric films integrated with CCD-devices.

V.V. Chernokozhin, E.Ph.

Pevtsov, M.A. Pospelova, and A.S. Sigov

Optimization and experimental verification of a pyroelectric bimorph radiation detector.

S.B. Lang, and M. Alexe

Oxide thin film heterostructure IR detectors.

A. Ignatiev, N.J. Wu, S.Q. Liu, and Y.Q. Xu

Preparation of La-modified Sr_{0.5}Ba_{0.5}Nb₂O₆ ferroelectric thin films for dielectric-bolometer-based infrared image sensor.

H. Xu, R. Kubo, Y. Yoshino, K. Hashimoto, M. Noda, and M. Okuyama

Laser interferometry for piezoelectric materials study - possibilities and limits.

M. Sulc, D. Barosova, and J. Fousek

Pyroelectrical property of a crystal phase in organosiloxane.

N.N. Matveev

Pyroelectric and piezoelectric studies on BSKNN ceramics.

K. Sambasiva Rao, M. Rajeswara Rao, and T.N.V.K.V. Prasad

Dielectric and pyroelectric properties of Pb(Mg_{1/3}Nb_{2/3})O₃-PbTiO₃ ceramics modified with MnO₂.

J.M. Jung, K.B. Kim, and S.W. Choi

New environmental infrared sensors.

J. De Frutos, A.M. Gonzales, M.C. Duro, F. Lopez, J. Meneses, A.J. De Castro, and J. Melendez

MONTREUX PAPERS

Investigation of the polarization depth distribution of PZT thick films by LMM.

B. Ploss, and W. Hässler

Effect of external field on pyro- and photoresponse of Sn₂P₂S₆ films.

A.A. Bogomolov, O.V.

Malyskhina, A.V. Solnyshkin, I.P.

Raevski, N.P. Protsenko, and

D.N. Sandjiev

On pyroelectrical property of ferroelectric ceramic spherical particles-polymer composites.

X.-P. Zou, L.-Y. Zhang, X. Yao,

L.-K. Wang, and F.-X. Zhang

Pyroelectric coefficient measurement using an RT6000 ferroelectric tester and CHAMBER software.

Y. Yamaguchi

Responsivity of four-layer pyroelectric detectors.

V.B. Samoilov, S.J. Kang, and

Y.S. Yoon

A dynamic method for determining the pyroelectric coefficient over an extended temperature range: 100K to 870K.

E. Stytsenko, and M. Daglish

Dielectric and pyroelectric properties of thin film PZT.

J.F. Roeder, I.-S. Chen, P.C. Van

Buskirk, H.R. Beratan, and C.M.

Hanson

Pyroelectricity and microstructure of Pb(Zr,Ti)O₃-related ceramics prepared through hot isostatic pressing.

O. Sugiyama, S. Saito, K. Kato,

S. Osumi, K. Murakami, and S.

Kaneko

POLYMERS, BIOLOGICAL AND ORGANIC MATERIALS - PROPERTIES AND APPLICATIONS

Thermo- and electrophysical research of ceramic-polymer boundary.

L. Pasechnik, A. Karpov, V.

Zavorotny, and Y. Yakimenko

Piezoelectric hydrostatic coefficients of PVDF and P(VDF, TrFE) copolymer foils at high hydrostatic pressures.

L. Burianova, P. Hana, and J.

Kulek

Effect of poling and ageing on high frequency dielectric and piezoelectric response of PVDF and PVDF/TrFE polymer foils.

C. Pawlaczyk, J. Kulek, and E.

Markiewicz

The formation of electret state in metalphthalocyanines.

R.I. Bunio, and G.M. Grigorovich

Low-temperature dielectric relaxation of PVDF.

N.D. Gavrilova, V.V.

Kochevinskii, A.M. Lotonov, I.A.

Malyskhina, and N.I. Kuznetsova

A solid state optical phantom for photon migration studies in turbid biological tissues.

M. Ozolinsh, and I. Lacis

Ferroelectricity in the biological membranes.

V.S. Bystrov, and N.K. Bystrova

Structure and dielectric parameters of hydrogels.

I.A. Malyskhina, N.D. Gavrilova,

E.E. Makhaeva, and A.R.

Khokhlov

Dielectric characteristics of the mixed crystals systems [(CH₃)₃NH]₃Sb₂(1-x)Bi₂xCl₉ (TCMACAB).

G. Bator, R. Jakubas, and J.

Mroz

Effect of dielectric relaxation on the performance of P(VDF-TrFE) copolymer ultrasonic transducers.

K.W. Kwok, H.L.W. Chan and

C.L. Choy

Preparation and microstructure of organic-inorganic fine composites P(VDF/TeFE)-SiO₂ by using sol-gel method.

X.-P. Zou, L.-Y. Zhang, and X.

Yao

PIEZOELECTRIC AND ELECTROSTRICTIVE BULK MATERIALS - PROPERTIES AND APPLICATIONS

Comparison between bimorphic and polymorphic bending devices.

R. Steinhäusen, W. Seifert, T.

Hauke, H.-T. Langhammer, H.

Beige, and H. Abicht

Influence of current distribution on generation of higher harmonic voltages in piezoelectric vibrator.

K. Ishii, A. Norihito, T. Shinjiro,

and I. Hideji

Calculation of the piezomoduli of depolarized piezoceramics.

A.G. Luchaninov

Influence of dielectric losses on the shift of the fundamental frequencies of thickness mode piezoelectric ceramic resonators.

J.L. San Emeterio, P.T. Sanz, and

A. Ramos

MONTREUX PAPERS

Elastic behavior of multilayer piezoceramic BaTi_{1-x}Sn_xO₃ in the lower MHz region.

U. Straube, H.T. Langhammer, H.-P. Abicht, and H. Beige

Infralow-frequency dispersion of piezoelectric and dielectric constants in PbTiO₃-based ferroelectric ceramics.

A.V. Turik, O.V. Pugachev, V.V. Volgin, and M.S. Novikov

PZT nanocomposites reinforced by small amount of oxides.

K.-I. Tajima, H.J. Hwang, M. Sando, and K. Niihara

Piezoelectric properties of chemically prepared W-doped Bi₄Ti₃O₁₂ ceramics.

M.V. Gracia, P. Duran, C. Moure, and J.F. Fernandez

Extension of an LVDT sensor system for thermal analysis for field-induced strain measurements of nonlinear ferroelectrics.

P. Wang, H. Raithel, S. Tomaschko, M. Hartweg, D. Haarer, and F. Stenzel

Contribution to the measurement of the electromechanical coupling factor k_{33} of the piezoelectric plates.

P. Hana, L. Burianova, D. Barosova, and J. Zelenka

Electromechanical hysteresis of electrostrictive ceramics.

E.P. Smirnova

Distortions on the output waveforms of high-voltage spike generations induced from piezoelectric loads.

P.T. Sanz, A. Ramos, and J.L. San Emeterio

Control of twinning of quartz plates by light beam scanning.

S. Noge, and T. Uno

Piezoelectric and elastic properties of β phase quartz.

T. Uno, and S. Noge

Temperature and frequency electromechanical characterization of LiNbO₃ type ceramics.

A. Megriche, P. Gonnard, and M. Troccaz

On various types of piezoelectric anisotropy in polydomain boracite crystals.

V.Y. Topolov, O. Crottaz, and J.-P. Rivera

Sn₂P₂S₆ compound as a material for solid state electronics.

E.D. Rogach

Investigation of acoustoelectric phenomena in Sn₂P₂S₆ single crystals.

V. Samulionis, J. Banys, and Y. Vysochanskii

Effect of NbLi doping on structure and piezoelectric properties of PZT type ceramics.

C. Tanasoiu, E. Dimitriu, and C. Miclea

NIST "ACMAT" database on ferro-piezoelectric and related materials.

Y. Cherner, and C. Sturrock

Piezoelectric and dielectric properties of pure and Mn doped strontium bismuth titanate.

C. Voisard, D. Damjanovic, and N. Setter

Temperature dependance of direct piezoelectric properties for relaxor-ferroelectric solid solutions undergoing a rhombohedral to tetragonal phase transition.

G. Robert, and D. Damjanovic

A diversity of nonmonotonic concentration dependences of piezoelectric properties in ferroelectric materials.

V.Y. Topolov

Crystalline structure and piezoelectric properties of a substituted lead titanate.

A.-M. Moisin, V. Vasilescu, A. Dumitru, A. Tekin, O. Addemirr, and K. Karakaya

Piezoelectric properties of Pb(Yb_{1/2}Nb_{1/2})O₃-PbTiO₃-PbZrO₃ ceramics.

H. Ohuchi, S. Tsukamoto, M. Ishii, and M. Hayakawa

Microstructural and piezoelectric properties on modified barium silver niobate ceramics.

K. Sambasiva Rao, and M. Rajeswara Rao

Piezoelectric coefficients obtained from the resonance admittance circle.

J. P. Rivera

Nonlinear measurement of piezoceramic resonators by the intermodulation method.

J.H. Kayombo, A. Albareda, R. Pérez, and E. Minguela

Processing and electromechanical properties of dome-shaped actuators fabricated by fused deposition of ceramics (FDC).

F. Mohammadi, A. Kholkin, S.

MONTREUX PAPERS

Danforth, and A. Safari

Structure and properties of high piezoelectric coupling $\text{Pb}(\text{B}'1/2\text{Nb}1/2)\text{O}_3$ binary systems.

A. Sternberg, L. Shebanovs, Y. Yamashita, M. Antonova, M. Livinsh, M. Tyunina, K. Kindzinsh, and I. Shorubalko

A novel piezoelectric actuator prepared by thick film technology.

W. Zhu, K. Yao, and Z. Zhang

A new LiNbO_3 surface acoustic wave transducer.

J. Nosek, E. Bigler, and W. Daniau

Domain contribution in the electric-field-induced strain of PZT ceramics measured by a Mach-Zehnder type interferometer.

T. Tsurumi, N. Ikeda, K. Okamoto, and N. Ohashi

High authority piezoelectric torsional actuators.

C. Kim, D. Lewis III, V. Degiorgi, D. Flippen, B. Bender, T. Jesson, C.C. Wu, M. Kahn, A. Pattnaik, Q. Zhang, V. Mueller, and A. Glazounov

Dielectric and electromechanical properties of $\text{PbNi}_{1/3}\text{Nb}_{2/3}\text{O}_3$ - PbTiO_3 - PbZrO_3 system: a processing-property study.

I.A. Cornejo, B. Jadidian, E.K. Akdogan, and A. Safari

New PZT formulation for actuators.

L. Eyraud, D. Audigier, and L. Lebrun

Acoustic emission in PZT ceramics after electric cycling.

D. Lupascu, M. Christmann, J.

Nuffer, and J. Rödel

0.9PMN-0.1PT ceramics as adaptive material.

M. Lejeune, S. Kurutcharry, E. Lattard, M. Oudjedi, and P. Abelard

Surface acoustic wave liquid sensor using dual mode delay line.

T. Nomura, A. Saitoh, and S. Furukawa

A review of recent developments in hydrophone technology.

K.M. Rittenmyer, W.A. Schulze, W.B. Carlson, and S.M. Pilgrim

Phase coexistence in PZT ceramics.

M.R. Soares

A nontrivial behavior of electromechanical coupling factors in PbTiO_3 -type ferroelectric ceramics.

Y.Y. Topolov, A.V. Turik, and A.I. Chernobabov

Space charge measurement using pulsed electroacoustic technique and signal recovery.

A. Vazques Carazo

Uniaxial stress and temperature dependence of field induced strains in antiferroelectric lead zirconate titanate stannat ceramics.

O. Essig, P. Wang, P. Jänker, and M. Hartweg

Microscopic and macroscopic ferroic and piezoelectric behavior of PZT and BaTiO_3 ceramics.

A. Endriss, M. Hammer, M.J. Hoffmann, A. Kolleck, and G.A. Schneider

The correlation between fatigue and material constants of PLZT

ceramics.

A. Levstik, V. Bobnar, Z. Kutnjak, C. Filipic, and M. Kosec

Processing and characterization of high Q_m ferroelectric ceramics.

C. Galassi, E. Roncan, F. Craciun, and C. Cappiani

Rayleigh behavior in the high field dielectric properties of ferroelectric ceramics.

D.A. Hall, and P.J. Stevenson

Pyroactive smart systems.

S.L. Bravina, and N.V. Morozovsky

A study of variation of piezoelectric activity of ferrosoft ceramics during polarization reversal.

G.M Akbaeva, V.Z. Borodin, Ya. V. Martynyuk, and V.A. Servuli

Piezoelectric resonance investigation of Zr-rich PZT at room temperature.

N. Cereceda, B. Noheda, J.R. Fdez.-Del-Castillo, J. de Frutos, A.M. Gonzalez, and J.A. Gonzalo

Miniature hydrophones from hollow ceramic spheres.

S. Alkoy, A.C. Hladky-Hennion, J.K. Cochran, and R.E. Newnham

Piezoelectric and optical properties of La-modified $\text{Pb}(\text{Sc}_{1/2}\text{Nb}_{1/2})\text{O}_3$ - PbTiO_3 binary ceramics near the morphotropic phase boundaries.

M. Adachi, K. Maruyama, T. Karaki, and A. Kawabata

Characterization of the piezoelectric ceramics mechanical

MONTREUX PAPERS

nonlinear behavior.

P. Gonnard, V. Gonnard, R. Briot, D. Guyomar, and A. Albareda

Surface acoustic wave properties on rotated Y-cut langasite single crystal substrates.

M. Kadota, T. Kitamura, and M. Kumatoriya

Neutron diffraction strain measurements of electroactive ceramics under dc fields.

S.T. Mixture, S. Pilgrim, C.T. Hicks, C.T. Blue, E.A. Payzant, and C.R. Hubbard

Stress dependence of electromechanical response of PMN-PT in the dc electrical field biased state.

J. Zhao, V. Müller, and Q.M. Zhang

Linear motor using hysteresis and resonance of piezoelectric element.

H. Okabe, and M. Kanno

Weak nonlinearities in piezoelectric transducers. Equivalent circuits.

R. Pérez, M. Minguella, and J.A. Gorri

Anomalous behavior of nonlinearity in a piezoelectric resonator.

R. Pérez, A. Alalbard, E. Minguella, and J.E. Garcia

Ferroelectric ceramics with included porosity for hydrophone applications.

E. Roncari, C. Galassi, F. Craciun, G. Guidarelli, S. Marselli, and V. Pavia

Different tuning contributions in piezoelectric transceivers improv-

ing transient signals for ultrasonic imaging.

A. Ramos, J.L. San Emeterio, and P.T. Sanz

Influence of the different loss factors on piezoelectric transducer performances.

L.P. Tran-Huu-Hue, F. Levassort, M. Lethiecq, and P. Audrain

Quantitative evaluation of multi-domain 36 °Cut LiTaO₃ wafer by line-focus-beam acoustic microscopy.

I. Takanaga, and J. Kushibiki

Influence of K¹⁺/La³⁺ co-modification on domain evolution and electrically-induced strains in lead zirconate titanate ferroelectric ceramics.

Q. Tan, J.-F. Li, and D. Viehland

Nonlinear piezoelectric response in ferroelectric ceramics driven at resonant mode.

S. Takahashi, M. Yamamoto, and Y. Sasaki

New piezoelectric KNbO₃ films for saw device applications.

K. Yamanouchi, H. Odagawa, T. Kojima, and Y. Cho

Concave cymbal transducers.

J. Zhang, J.F. Tressler, A. Dogan, and R.E. Newnham

Analytical and computer designing and calculation of piezotransformers.

A.A. Yerofeyev, and S.A. Yerofeyev.

Prediction of piezoresonators operational characteristics.

A.A. Yerofeyev, and S.A. Yerofeyev

A non-linear approach of resonant piezolayer.

P.J. Liebe, and D. Guyomar

Performance criteria and figure-of-merits for hydroacoustic sensors and materials.

K.M. Rittenmyer, and T.B. Gabrielson

Piezoelectric properties of PB(InTa)1/2O₃-PBTiO₃ solid solution system.

E.F. Alberta, and A.S. Bhalla

Phenomenological and structural properties of piezoelectric ceramics based on xPb(Zr,Ti)O₃-(1-x)Sr(K_{0.25}Nb_{0.75})O₃ (PZT/SKN) solid solutions.

G. Helke, S. Seifert, and S.J. Cho

Electrostriction measurements on low permittivity ceramics and polymers.

R. Yimnirun, S. Eury, V. Sundar, P. Moses, S.J. Jang, and R.E. Newnham

Piezoelectric non-resonant transducer to measure high voltage.

A. Vazquez Carazo

Single point diamond turning machining of ferroelectric materials.

P.A. Beltrao, J. Corbett, A.E. Gee, R.W. Whatmore, C.A. Goat, and S.A. Impey

Temperature dependence of piezoelectric, dielectric and elastic properties of PLZT ceramics.

V. Bobnar, Z. Kutnjhak, and A. Levstik

MONTREUX PAPERS

Dielectric pyroelectric and electro-mechanical properties of the $\text{Pb}_{5-x}\text{Ba}_x\text{Ge}_3\text{-ySi}_y\text{O}_{11}$ (PBGS) ferroelectric glass-ceramic system.

I.A. Cornejo, A. Safari, and M.J. Haun

A new procedure for the characterization of piezoelectric samples in non standard resonant modes.

A.M. Gonzalez, J.de Frutos, and M.C. Duro

Use of ferroelectrics for gas purification.

M. Duta, and F. Stefanescu.

COMPOSITES

Study on $\text{BaTiO}_3/\text{P}(\text{VDF-TrFE})$ 0-3 composites.

H.L.W. Chan, M.C. Cheung, and C.L. Choy

An investigation into the use of glass and carbon fibre reinforced piezoelectric composites as micro-actuators.

C. Chilumbu, D.F.L. Jenkins, and W.W. Clegg

Homogenization of piezocomposites containing both 0-3 and 3-3 connectivities.

F. Levassort, M. Lethiecq, R. Desmare, and L.P. Tran-Huu-Hue

Fabrication of a curved ceramic/polymer composite medical imaging transducer by fused deposition of ceramics (FDC).

G.M. Lous, I.A. Cornejo, A. Safari, and S.C. Danforth

Anisotropic properties of electric-field structured piezoelectric composite materials.

S.A. Wilson, and R.W. Whatmore

On a large piezoelectric anisotropy in a three-component composite with a variable connectivity.

V.Yu. Topolov, and A.V. Turik

Processing, evaluation, and electro-mechanical properties of large-area flexible-array piezoelectric ceramic/polymer composite transducer for bone healing acceleration.

I.A. Cornejo, B. Jadidian, and A. Safari

Finite element analysis of the composite transducers utilizing different piezoelectric coefficients.

A. Dogan, A.C. Hladky, and R.E. Newnham

Design and fabrication of volume fraction gradient (VFG) piezoelectric composites for medical imaging applications.

R. Panda, and A. Safari

Fine-scaled piezoelectric 1-3 composites: new approaches of cost effective fabrication.

S. Starke, A. Schönecker, and W. Gebhardt

Fine scaled piezoelectric 1-3 composites: properties and modeling.

R. Steinhausen, W. Seifert, T. Hauke, H. Beige, W. Watzka, S. Seifert, D. Sporn, S. Starke, and A. Schönecker

ACTIVE CONTROL

Potentialities of 0.9PMN-0.1PT ceramics for active vibration control.

S. Kurutcharry, M. Lejeune, M.

Oudjedi, and P. Abelard

Development and characterization of novel, high-displacement piezoelectric actuators for aerospace systems.

S.A. Wise

BULK CERAMIC PROPERTIES: DIELECTRIC AND OTHER

Effect of dolomite addition on electrical properties of ceramics derived from kaolinite.

S. Achour, A. Boucekkine, A. Harabi, and S.E. Barama

Electrical and phase heterogeneity of the BaTiO_3 and BaTi_4O_9 based ceramics: scanning force microscopy study.

V. Bovtun, H. Sturm, W. Stark, and E. Schulz

Synthesis and dielectric properties of $\text{Ba}_{1-x}\text{R}_2\text{x}/3\text{Nb}_2\text{O}_6$ (R: rare earth) with tetragonal tungsten bronze structure.

N. Wakiya, J.-K. Wang, S. Tada, A. Saiki, K. Shinozaki, and N. Mizutani

Dielectric properties of porous $\text{Ba}_{0.997}\text{La}_{0.003}\text{Ti}_{1.0045}\text{O}_3$ ceramics.

P.Q. Mantas, and M.E.V. Costa

Grain size effects in barium titanate.

W.A. Schulze, and S.P. Ostrander

Dielectric properties of barium-titanate sintered from tribophysically activated powders.

B.D. Stojanovic, V.B. Pavlovic, S. Duric, B. Marinkovic, and M.M. Ristic

MONTREUX PAPERS

Peculiarities of dielectric properties of some compositions of PZT-based ferroceramics.

A.V. Shil'nikov, R.H. Uzakov, I.V. Otsarev, V.N. Nesterov, A.I. Burkanov, and G.M. Akbaeva

Crystal chemistry, dilatometric studies and dielectric properties lithium tantalate and manganese oxides-based ceramics.

M. Zrioul, A. Assani, and B. Elouadi

Dielectric properties of SrTiO₃:PMN ceramics.

V.V. Lemanov, A.V. Sotnikov, E.P. Smirnova, M. Weihnacht, and W. Haessler

Dielectric properties of cobalt and chromium doped lead iron tungstate ceramics.

C. Miranda, P.M. Vilarinho, and L. Zhou

Effect of Nb/Co addition on the dielectric properties of BaTiO₃.

A. Mortazavi, and A. Beitollahi

Growth and dielectric studies on ferroelectric Ce:Ba_{1-x}Sr_xTiO₃ single crystals.

R. Varatharajan, R. Jayavel, C. Subramanian, and P. Ramasamy

The critical conditions of non-regular behavior of the series resonant circuit with a ferroelectric capacitor.

S.N. Drozhdin, A.Yu. Shchekotov, B.I. Ogienko, and O.N. Shapovalova

The modification of high-voltage porcelain structure with the aid of mineralisators.

G.N. Maslennikova, and T.I. Koneshova

Uniaxial stress effects on the permittivity of ferroelectric and relaxor ceramics.

O. Steiner, E.L. Colla, A.K. Tagantsev, and N. Setter

Time dependence of mechanical depolarization at ferroelectric ceramics.

K.H. Härdtl, and C. Heilig

Dielectric behavior of quenching PLZT 7/70/30 ceramics.

Z.-Y. Cheng, A. Guo, X. Yao, and R.S. Katiyar

Characterization of elastic homogeneity of commercially available optical-grade LiTaO₃ crystals by LFB acoustic microscopy.

J.-I. Kushibiki, and T. Okuzawa

BAS-glasses for high temperature applications.

K. Eichler, P. Otschik, G. Solow, and W. Schaffrath

Structural and dielectric properties of lanthanum modified barium lithium niobate ceramics.

K. Sambasiva Rao, K. Koteswara Rao, T.N.V.K.V. Prasad, and M. Rajeswara Rao

Microstructural, dielectric and resistivity studies on modified barium titanium niobate ceramics.

K. Sambasiva Rao, and M. Rajeswara Rao

Thermal properties of solid solution Bi₄Ti₃-xCu_xO₁₂ (0.005<x<0.25).

M.E. Mendoza-Alvarez, E. Lopez-Cruz, and C. Tabares-Munoz

Stabilization and dielectric properties of perovskite La₂/3TiO₃ compound.

S. Skapin, D. Kolar, and D. Suvorov

NIST database "ACMAT" on ferroelectric compounds and materials - tool for materials scientists.

Ya. Cherner, G.A. Geguzina, and J. Rumble

Properties of donor doped BaTi(Mn,Mg)O₃ + SiO₂ sintered in reducing atmospheres.

D.I. Spang, A. Safari, and I. Burn

Effect of Zr and La on ferroelectric properties of Pb_{0.6}Ba_{0.4}Nb₂O₆.

V.V.N. Acharya, K.V.S. Ramam, and A. Bhanumathi

Paraelectric and elastic properties of ceramic with nominal composition (A₁-cA'_c)(B B')O₃ (A,A'=Ba,Sr,Ca).

H. Ikawa, M. Yamashiro, M. Fukuhara, and M. Takemoto

Changing dielectric properties of ferroelectric ceramics by mechanical stresses.

A.V. Turik, and E.N. Sidorenko

Phase structures and dielectric properties of complex perovskite ceramics containing lead titanate.

X. Wang

Investigations on the bulk sintering of a new Z5U ceramic composition for capacitor applications.

P. Sasidharan, P.A. Abraham, and R. Ratheesh

K₂Sr₄Nb₁₀O₃₀-based dielectric ceramics having the tetragonal tungsten bronze structure and a

MONTREUX PAPERS

temperature stable high permittivity.

B. Tribotte, J.M. Haussonne, and G. Desgardin

Dielectric and ferroelectric properties of rare earth doped SBN ceramics.

D.U. Spinola, I.A. Dos Santos, L.A. Bassora, J.M. Pova, J.A. Eiras, and D. Garcia

The effect of grain size on the high field dielectric properties of hard PZT ceramics.

D.A. Hall, and P.J. Stevenson

MECHANICAL PROPERTIES

Weibull analysis of the bending behavior of soldered CMC.

K. Franken, and H.R. Maier

The effect of grinding conditions on lead zirconate titanate machinability.

C.A. Goat, and R.W. Whatmore

Thermal behavior of the elastic (Young) modulus in SBN-derived compounds (Bi₂SrNb₂O₉).

B. Jimenez, P.D. Martin, and R.J. Jimenez-Rioboo

Anisotropic fracture toughness of PZT.

J.M.C. Moreno, F. Guiu, M.J. Reece, and M. Meredith

Application of ceramic coatings to increase exploitation characteristics of modern electric machines.

A. Balitskii

Residual stresses in layered ceramic composites.

H. Tomaszewski

Cyclic fatigue-crack propagation in ferroelectric ceramics.

H. Weitzing, G.A. Schneider, J. Steffens, M. Hammer, and M. Hoffmann

FUNDAMENTAL STUDIES, DOMAIN WALL PROCESSES, PHASE TRANSITIONS, STRUCTURE

Investigation of the character of the phase transitions in Nb doped Zr-rich PZT by pyroelectric and dielectric measurements.

N. Cereceda, B. Noheda, and J.A. Gonzalo

FRL-FRH phase transition behavior in the stacked Pb₉Zr_{1-x}Ti_xO₃ perovskite ceramics.

N. Duan, D. Sun, X. Dong, and S. Lin

Pulsed neutron diffraction of Zr-rich PZT.

B. Noheda, J.A. Gonzalo, M. Hagen, and U. Steigenberger

SEM investigation of domain structure in 9Ba,Ca,PbTiO₃.

Lj. Zivkovic, B.D. Stojanovic, Z. Nikolic, B. Marinkovic, and T. Sreckovic

Granularity influence on the phase transition sequence of Pb₅Al₃F₁₉.

J. Ravez, A. Simon, S. Sarraute, and J.C. Niepce

Changes in ordered structure and dielectric properties with the A-site and B-site cation ratios of complex perovskites (Sr_{1-x}Ba_x)(Sr_{0.33+y}Ta_{0.67-y})O_{3-d}.

J. Takahashi, T. Fujii, S. Shimada, and K. Kodaira

Dielectric properties in the vicinity of phase transition of new ferroelectric CuInP₂S₆.

J. Banys, V. Samulionis, and V. Cajipe

Linear birefringence and ultrasonic studies of phase transition in (CH₃)₂NH₂H₂PO₄ crystal.

Z. Czapla, J. Furtak, B. Kosturek, J. Hator, and T. Osaka

Raman spectroscopy investigation of the low temperature phase of PLZT 4/95/5 and 4/90/10.

H. Hassan, G. Kugel, and D. Viehland

Thermal hysteresis of light scattering intensity in ferroelectric barium sodium niobate crystals.

S.V. Ivanova

Optical investigations of phase transition in N(CH₃)₄FeCl.

B. Kosturek, D. Podsiadla, and Z. Czapla

Comparative dielectric and Raman spectroscopy study of silver perovskite ceramics AgNb_{1-x}Ta_xO₃ and Ag_{1-x}Na_xNbO₃.

W. Fortin, M. Hafid, A. Kania, and G. Kugel

Order-disorder nature of ferroelectric phase transition in stoichiometric LiNbO₃ crystal.

S. Kojima

On some ferroelasticity theory.

K.A. Lazopoulos

Anomalies of thermal properties at crystal-crystal transition in cellulose.

N.N. Matveev, and V.V. Postnikov

MONTREUX PAPERS

Dipole relaxation processes in electron-irradiated amorphous chalcogenide systems.

O.I. Shotyuk

Pressure effects in dimethylammonium gallium sulfate (DMAGaS).

N. Yasuda, A. Kaneda, and Z. Czapla

Calculation and experimental data on emission currents and polarization in thin layer metal-ferroelectric-metal structures.

V.M. Bogomol'nyi

Ultrasonic study on phase transition sequence in betaine phosphite.

E.V. Balashova

The electronic structure investigation of the oxides series with pyrochlore type spatial structure.

T.N. Bondarenko, S.V. Borisenko, V.N. Uvarov, Y.A. Teterin, A.N. Yaresko, V.P. Dzeganzovskii, A.M. Sych, and Y.A. Titov

Electron emission out of triglycine-sulphate with different bias field.

S.D. Milovidova, A.S. Sidorkin, and O.V. Rogazinskaya

Heterophase structure and dynamic behavior in the vicinity of non-equilibrium phase transitions.

R.F. Mamin

A comparative study of the grain size effects on ferro-para phase transition in barium titanate ceramics.

L. Mitoseriu, V. Tura, C. Papuso, T. Osaka, and M. Okuyama

Effects of structure ordering in complex ferroelectric perovskites.

A. Sternberg, E. Birks, and L. Shebanovs

Dynamics of the plane domain walls and Barkhausen noise in gadolinium molybdate.

V.Y. Shur, E.L. Rumyantsev, V.L. Kozhevnikov, A.L. Subbotin, E.V. Nikolaeva, and E.I. Shishkin

Low-frequency dielectric response of KTaO₃:5%Li crystals.

A.V. Sotnikov, V.V. Lemanov, M. Weihnacht, and R. Kunze

Peculiarities of dielectric relaxation in Ba_xSr_{1-x}TiO₃ (x=0.005-0.2).

A.V. Sotnikov, V.V. Lemanov, E.P. Smirnova, M. Weihnacht, and R. Kunze

Domain structure of epitaxial PbTiO₃/(001)MgO thin films.

L.A. Sapozhnikov, I.N. Zakharchenko, E.V. Sviridov, S.I. Shevtsova, and V.A. Alyoshin

ESR of Gd³⁺ probe in lead germanate crystals.

M.P. Trubitsyn

ESR and Raman scattering investigations of incommensurate Rb₂ZnCl₄:Mn²⁺.

M.P. Trubitsyn, V.I. Pastukhov, and T.M. Bochkova

On the phase transitions peculiarities in ferroelectric-semiconductors.

E.A. Dul'kin, and I.P. Raevski

Surface waves in polydomain ferroelectric crystals.

B.M. Darinsky, and A.S. Sidorkin

Response of domain structures in electroded ferroelectrics to external electric fields.

A. Kopal, P. Mokry, T. Bahnik, and J. Fousek

Orientational dynamics of Li dipoles in K_{1-x}Li_xTaO₃ studied by hyper-Rayleigh scattering.

H. Vogt

Dielectric relaxation in metal-ferroelectric PZT-metal thin film structures.

V.V. Lemanov, S.P. Teslenko, and V.K. Yamarkin

Landau theory-based analysis of field dependence of hysteresis loops in.

C. Harangea, and M. Okuyama

Kinetics of polar nanoregions and nanoscale polydomain clusters in relaxor (6-8)/65/35 PLZT ceramics.

V.Y. Shur, G.G. Lomakin, V.P. Kuminov, S.S. Beloglazov, S.V. Slovikovskii, A. Sternberg, and A. Krumins

Vacuum emission of electrons from PTC thin films.

K. Biedzycki, and L. Markowski

Ferroelectric domain switching of stoichiometric LiNbO₃ with low electric field.

K. Kitamura, Y. Furukawa, V. Gopalan, and T.E. Mitchell

Observation of domain nucleation and growth during switching process.

S. Hong, E.L. Colla, E. Kim, K. No, A.K. Tagantsev, P. Muralt, and N. Setter

Finite-element modeling of ferroic

MONTREUX PAPERS

domain switching in piezoelectric ceramics.

T. Steinkopff

The analysis of dynamic domain boundaries of crystals TGS in low and infralow frequencies electrical fields.

A.V. Shil'nikov, A.P.

Pozdnyakov, V.N. Nesterov, and R.H. Uzakov

Grain size effects on ferroelectric phase transitions in nano-crystalline complex perovskite electroceramics.

R.S. Katiyar, and M. Jinfang

Ferroelectric properties of filed tungsten bronze single crystals $(\text{Ba}_{1-x}\text{Sr}_x)_2\text{Na}_{1-y}\text{K}_x\text{Nb}_5\text{O}_{15}$.

R. Guo, Y. Jiang, and A. Bhalla

Off-equilibrium dynamics in PLZT relaxor system.

Z. Kutnjak, C. Filipic, A. Levstik, and R. Farhi

Optical mode softening of $\text{SrBi}_2\text{Ta}_2\text{O}_9$ and related bismuth layer ferroelectrics.

S. Kojima

Novel ferroelectricity in polar semiconductor ZnO by Li-substitution.

A. Onodera, N. Tamaki, H. Satoh, and H. Yamashita

Size effects in ferroelectrics studied using the transverse Ising model.

Y.G. Want, Kleeman, and W.L. Zhong

Four kinds domain study of pure and Mn-doped PbTiO_3 single crystals by atomic force and Kelvin force microscopy.

T. Yamamoto, S. Omika, and

T. Ida

Electron emission from and switching kinetics of ferroelectric thin films.

D. Averty, H. Gundel, R. Seveno, and R. Le Bihan

Neutron diffraction studies of the relaxor ferroelectric $\text{Pb}(\text{Sc}_{0.5}\text{Ta}_{0.5})\text{O}_3$.

K.Z. Baba-Kishi

Special properties of "strange" domain walls.

W. Cao, and J. Fousek

Writing of sub micrometer ferroelectric domains with a scanning force microscope.

M. Abplanalp, and P. Günter

Imaging polarization vectors and domain patterns in ferroelectric BaTiO_3 ceramics using voltage modulated scanning force microscopy.

G.A. Schneider, U. Köpke, J.M. Saldana, L.M. Eng, and H.-J. Güntherod

Effect of semiconductive parameters on the electron emission from ferroelectric ceramics.

I. Raevski, and A.N. Pavlov

Universal law dielectric response in polyimides with quinuclidine groups.

N.D. Gavrilova, I.A. Malyshkina, L.G. Bradulina, and Y.S. Vigodsky

Investigations of zirconium rich PZT ceramics and crystals by ESR and NMR methods.

I.P. Bykov, M.D. Glinchuk, and V.V. Laguta

Phase Transitions in $\text{Pb}(\text{Mg}_{1/4}\text{Zn}_{1/4}\text{W}_{1/2})\text{O}_3$ ceramic.

S.N. Choudhary, S.K. Sinha, K. Prasad, and R.N.P. Choudhary

Transient absorption and relaxation processes in irradiated KNbO_3 .

L. Grigorjeva, D. Millers, E.A. Kotomin, and E.S. Polzik

The squeezed phonon states and the phase transitions in pyroelectrics.

A.F. Klinskikh

The structure and dynamics of the polaronic excitations in the dipolar crystals.

A.F. Klinskikh

ESR investigations of ferroelectric phase transition in $\text{Li}_2\text{Ge}_7\text{O}_{15}:\text{Mn}^{2+}$.

M.P. Trubitsyn, M.D.

Volnianskii, and A.Y. Kudzin

Influence of x-irradiation on the polarization reversal properties of doped TGS crystals.

L.N. Kamysheva, S.N. Drozhdin, O.M. Golitsyna, and T.N. Podgornaya

Absorption spectra of crystals A_2CuCi_4 with organic cations and their structural properties.

S. Kaluza, and M. Suchanska

Relaxation of the domain structure in deuterated triglycine sulphate crystal.

S.N. Drozhdin, and M.A. Kuyantsev

Submillimeter BWO-spectroscopy of the ferroelectric soft mode in SrTiO_3 .

A.A. Volkov, B.P. Gorshunov,

MONTREUX PAPERS

A.V. Pronin, and A. Loidl

Raman scattering and x-ray diffraction investigations of sol-gel derived $\text{Sr}_{1-x}\text{Ba}_x\text{Nb}_2\text{O}_6$ nano-powder.

M.M.T. Ho, C.H. Luk, C.H. Mak, and K.H. Wong

Ionic site occupancy and displacement in ferroelectric lead barium niobate single crystals.

R. Guo, H.T. Evans Jr., and A.S. Bhalla

Non-stationary phenomena in ferroelectric semiconductor $\text{Sn}_2\text{P}_2\text{Se}_6$.

S.L. Bravina, A.N. Morozovska, and N.V. Morozovsky

Curie temperature dependencies on the interatomic bond characteristics for Bi-contained layered perovskite-like ferroelectrics.

G.A. Geguzina

Correlations between T_c of binary NaNbO_3 -based solid solutions and interatomic bond characteristics.

G.A. Geguzina, K.E. Vasil'chenko, L.A. Resnitchenko, and N.V. Dergunova

Dielectric properties and phase transitions in Sr-substituted $\text{Pb}(\text{Mg}_{1/2}\text{W}_{1/2})\text{O}_3$.

J.H. Kim, and W.K. Choo

Dielectric properties and the phase transition behavior of $\text{Pb}(\text{Yb}_{1/2}\text{Nb}_{1/2})\text{O}_3$ - $\text{Pb}(\text{Fe}_{1/2}\text{Nb}_{1/2})\text{O}_3$ pseudobinary system.

B.J. Kuh, D.C. Choi, and W.K. Choo

The influence of ferroelastic domain structure on thermal conductivity of $\text{Gd}_2(\text{MoO}_4)_3$.

S. Mielcarek, B. Mroz, P. Piskunowicz, Z. Trybula, M. Bromberek, and Z. Tylczynski

Bulk periodically poled lithium niobate: impurity modulation and domain structure.

I.I. Naunmova, N.F. Evlanova, O.A. Gilko, S.V. Lavrishchev, and S.A. Blokhin

Kinetic first order pyrochlore-perovskite phase transition in PZT thin-films.

I.P. Pronin, S.A. Kukushkin, A.V. Osipov, E.Yu. Kaptelev, and V.N. Detzik

Crystal structure and domain-wall orientations of antiferroelectric $\text{Pb}(\text{Yb}_{1/2}\text{Nb}_{1/2})\text{O}_3$.

K.H. Park, H.J. Lee, and W.K. Choo

T.E.M. investigation of rhombohedral PZT thin films.

J. Ricote, Q. Zhang, and R.W. Whatmore

Growth of the 90° - domains in C-plates of NaNO_2 .

Y. Tokugawa, and Y. Yamada

The effect of high uniaxial stress on elastic properties and internal friction of ferroceramics at phase transitions.

V.M. Tsaplev

Change of micro and macro symmetry of barium titanate single crystal around Curie temperature and its model.

S. Wada, T. Suzuki, T. Norma, M. Osada, and M. Kakihana

Direct imaging of ordered structures in undoped and La-doped $\text{Pb}(\text{Mg}_{1/3}\text{Nb}_{2/3})\text{O}_3$.

Z. Xu, D. Viehland, Y. Yan, M.F. Chisholm, and S.J. Pennycook

Imaging of ferroelectric domains with sub micrometer resolution by scanning force microscopy.

M. Abplanalp, and P. Günter

High resolution proton spectra in triglycine sulphate crystals.

G.I. Ovtchinnikova, A.V. Kutysenko, and N.D. Gavrilova

Impurities and radiation defects in TGS dielectric spectra.

G.I. Ovtchinnikova, N.D. Gavrilova

Li - containing ceramics with GWS structure as new disordered ferroelectric materials.

V.G. Kryshchok, and E.N. Sidorenko

RELAXORS

Dielectric response of relaxor ferroelectrics.

M.D. Glinchuk, and V.A. Stephanovich

Role impurities in relaxor behavior of $\text{Cd}_2\text{Nb}_2\text{O}_7$ ferroelectric.

N.N. Kolpakova, M. Wiesner, A.O. Lebedev, P.P. Syrnikov, and V.A. Khramtsov

The processes of polarization and repolarization in relaxors with the tungsten bronze structure.

R.H. Uzakov, A.V. Shil'nikov, and A.I. Burkhanov

MONTREUX PAPERS

A study on the dielectric properties and diffuse phase transition of the (1-c)Pb(Yb_{1/2}Nb_{1/2})O₃-cPbZrO₃ binary system.

K.V. Im, J.-H. Kim, and W.K. Choo

Compositional ordering effects in (1-x)PbSc_{1/2}Nb_{1/2}O₃-xPbSc_{1/2}Ta_{1/2}O₃ solid solution crystals.

I. Raevski, V.V. Eremkin, V.G. Smotrakov, E.S. Gagarina, and M.A. Malitskaya

A dielectric and Raman scattering study of ceramics with composition Ba(Ti_{1-x}Zr_x)O₃.

A. Simon, M. El Marssi, R. Farhi, and J. Ravez

Ferroelectric switching and relaxor properties of Sr_xBa_{1-x}Nb₂O₆ crystals doped with rare-earth elements.

T. Volk, V. Salobutin, Th. Woike, H. Schmitz, R. Pankrath, and M. Woehlecke

Static and dynamic properties of relaxor ferroelectrics.

M.D. Glinchuk, and V.A. stephanovich

Relaxor ferroelectrics in non-linear systems.

M. Ozolinsh, D. Hanstorp, and S.T. Lagerwall

Dielectric response of a lead magnesium niobate based ceramic under various alternating fields.

Y. Wang, Z.L. Gui, Y.C. Chan, and L.T. Li

Microstructure and dielectric properties of relaxor perovskite ceramics.

S. Ananta, and N. Thomas

Study of dielectric and photoelectric properties of Pb(Mg_{1/3}Ta_{2/3})O₃.

A.A. Bokov, M.A. Malitskaya, and I.P. Raevski

Preparation of PbB_{1/2}³⁺Nb_{1/2}⁵⁺O₃ ceramics with differing degree of compositional ordering by liquid-phase sintering.

I. Raevski, V.Yu. Shonov, M.A. Malitskaya, E.S. Gagarina, V.V. Eremkin, and V.G. Smotrakov

Relaxor ferroelectricity in ceramics with composition Ba_{1-x}K_x(Ti_{1-x}Nb_x)O₃.

J. Ravez, and A. Simon

PIEZOELECTRIC AND ELECTROSTRICTIVE THIN FILM MATERIALS, PROPERTIES AND DEVICES

Fabrication of oriented silicon-based polymer thin film and its application to surface acoustic wave sensor.

S. Furukawa, and T. Nomura

The characterization of PZT films of differing orientations for MEMS applications.

D.F.L. Jenkins, W.W. Clegg, G. Velu, E. Cattani, and D. Remiens

Deposition of piezoelectric (PZT) thin films by excimer laser ablation for piezoelectric application.

K. Kikuchi, R. Maeda, A. Schroth, A. Umezawa, and S. Matsumoto

Surface acoustic wave propagation in PZT/YBCO/SrTiO₃ epitaxial heterostructures.

A. Mansingh, R. Nayak, and K. Steenivas

Accelerometers based on PZT thin films.

J. Baborowski, S. Hediger, P. Murali, and Ch. Wuethrich

Sputter deposition of ZnO thin films for SAW sensors.

D.A. Hall, and V.P. Kutepova

Direct techniques for the characterization of the piezoelectric coefficients (d₃₃ and d₃₁) of thin films.

J.F. Shepard Jr., F. Xu, F. Chu, R. Polcawich, and S. Trolier-McKinstry

Preparation and electromechanical properties of PMN-PT thin films.

Z. Kighelman, A. Seifert, and D. Damjanovic

Sol-gel derived Pb(Zr,Ti)O₃ thick films for piezoelectric actuated micro-electro-mechanical system (MEMS).

B.J. Kim, J. Lee, and J.B. Yoo

High-resolution dry etch patterning of PZT for piezoelectric MEMS devices.

R. Zeto, B.J. Rod, M. Dubey, M.H. Ervin, R.C. Piekarz, S. Trolier-McKinstry, T. Su, and J.F. Shepard

Clamping of piezoelectric thin films on substrates: influence on the effective piezoelectric modulus d₃₃.

R. Steinhilber, T. Hauke, W. Seifert, V. Müller, H. Beige, S. Seifert, P. Löbmann, and D. Sporn

Piezoelectric and dielectric properties of sputter deposited (111), (100), and random-textured Pb(Zr_xTi_{1-x})O₃ (PZT) thin films

MONTREUX PAPERS

as a function of the composition.
S. Hiboux, and P. Muralt

e31 remanent piezoelectric constant of PZT thin films.

E. Cattani, T. Haccart, G. Vellu, and D. Remiens

Characterization of piezoelectric thin films.

D.G. Kim, and H.G. Kim

Poling effect on the piezoelectric properties of lead zirconate titanate thin films.

A.L. Kholkina, D.V. Taylor, S. Hiboux, and N. Setter

Characterization of pulsed-laser deposited Pb(Zr,Ti)O₃ for piezoelectric thin film devices.

P. Veradi, F. Craciun, M. Dinescu, and L. Mirengi

THIN FILM PROPERTIES

Specific heat behavior in epitaxial ferroelectric BaTiO₃ thin film.

A. Onodera, and Y. Kawamura

The dielectric properties of (Ba,Sr)TiO₃/MgO thin films.

S. Sengupta, and J.-P. Maria

The measuring of the heat capacitance and thermal conductivity of thin dielectric films on a substrate.

S.T. Davitadze, B.A. Strukov, S.N. Kravchun, V.V. Lemanov, B.M. Goltzman, and S.G. Shulman

Microstructure and properties of highly oriented PZT thin films on epitaxial ceramic electrodes prepared by CSD.

U. Hasenkox, and R. Waser

Chemical solution deposition (CSD) and characterization of the solid solution series Ba(1-x)Pb_xTiO₃.

D. Bolten, M. Hoffmann, U. Hasenkox, O. Lohse, and R. Waser

Dependence of electrical properties of sputtered PZT thin films on their bottom electrodes and their thermal treatments.

B. Ea Kim, F. Ayguavives, F. Vamière, M.F. Ravet, M.C. Hugon, and B. Agius

Preparation and properties of PGO thin films by PLD.

S.-M. Koo, L.-R. Zheng, Q.-R. Yin, B.-M. Moon, K.V. Rao

Fatigue and nonlinear dielectric and piezoelectric response of PZT thin films.

D.V. Taylor, D. Damjanovic, and E.L. Colla

Tunneling conduction in virgin and fatigued states of PZT films.

I. Stoichnov, A.K. Tagantsev, E.L. Colla, and N. Setter

Influence of the deposition temperature and Pb species flux on the characteristics of PbTiO₃ thin films deposited by sputtering on optical fibers.

C.A.P. Muller, and P. Muralt

Electrical properties and microstructural evolution of porous Pb_{1-x}CaxTiO₃ pyroelectric thin films.

A. Seifert, P. Muralt, and N. Setter

Bulk charge influence on ferroelectric PZT thin films properties.

A.V. Zakharov, E.D. Rogatch, and E.V. Sviridov

The effect of film thickness on the ferroelectric properties of sol-gel prepared lanthanum modified lead titanate thin films.

M. Alguero, M.L. Calzada, and L. Pardo

Dielectric films in the microwave region.

D.C. Dube

Physical origin of conduction in PZT thin films.

I. Stolichnov, and A.K. Tagantsev

Poling of ferroelectric thin films.

M. Kohli, P. Muralt, and N. Setter

Nonlinear contributions to dielectric and piezoelectric properties in PZT thin films.

D.V. Taylor, and D. Damjanovic

Thickness dependence of PZT thin film ferroelectric properties.

L. Baudry, E. Cattani, G. Vellu, J. Tournier, and D. Remiens

Dependence of electrical properties of Pb(Zr,Ti)O₃ thin films on the grain size and film thickness.

H. Fujisawa, S. Hyodo, Y. Ishii, N. Tomozawa, M. Shimizu, and H. Niu

Electrical characterization of ferroelectric YMnO₃ films for MF(I)S-FET application.

N. Fujimura, T. Yoshimura, and T. Ito

Electrical properties of strain-induced epitaxial (Ba,Sr)TiO₃ thin films.

MONTREUX PAPERS

S. Jun, and J. Lee

Effect of thickness on the dielectric properties of $\text{Pb}(\text{Mg}_{1/3}\text{Nb}_{2/3})\text{O}_3$ (PMN) thin film prepared by sol-gel method.

N. Mizutani, N. Wakiyua, J.-W. Moon, T. Kiguchi, O. Sakurai, and K. Shinozaki

Sol-gel PTC BaTiO_3 thin films.

T. Ogawa, O. Sugiyama, S. Saitoh, S. Miyahara, A. Akahori, M. Yajima, H. Masuda, K. Satoh, H. Satoh, M. Kobayashi, and K. Nozaki

Influence of ion implantation of the ferroelectric properties of $\text{Pb}(\text{Zr,Ti})\text{O}_3$ films.

W. Biegel, B. Wörz, M. Hanika, R. Klamann, M. Kuhn, and B. Stritzker

Growth and characterization of ferroelectric $\text{LaTiO}_{3.5}$ thin films.

J. Fompeyrine, T. Tybel, J.W. Seo, C.H. Ahn, J.-M. Triscone, and J.-P. Locquet

Quantitative determination of the dielectric constant of the intermediate layer in PZT ferroelectric capacitors.

A.T. Bartic, D. Wouters, J. Sing, G. Norga, H. Bender, and H. Maes

Preparation and dielectric properties of $\text{SrBi}_2\text{Ta}_2\text{O}_9$ thin films by sol-gel method.

T. Hayashi, T. Hara, and S. Sawayanagi

Dielectric aging of ferroelectric $\text{Sn}_2\text{P}_2\text{S}_6$ thin films.

E.D. Rogatch, and N.A. Korchagina

Breakdown mechanism in insulating zinc oxide film.

V. Gupta, and A. Mansingh

Gas sensing characteristics and transformation phenomena in Fe-O thin film.

B.J. Kim, E.T. Lee, and G.E. Jang

Investigation of factors affecting electrical properties of PZT thin films.

H. Kanai, Y. Yamashita, and K. Yamakawa

Electric characteristics of the PZT capacitors using Ir electrodes.

K. Kondo, K. Takai, K. Matsura, T. Tamura, H. Ashida, and S. Otani

Effect of insulator on memory window of metal ferroelectric insulator semiconductor field effect transistor (MEFISFET)-non destructive devices.

Y.T. Kim, C.W. Lee, D.S. Shin, and H.N. Lee

Enhancement of memory window in the metal/ferroelectric/insulator/semiconductor field effect transistor.

H.H. Lee, and Y.T. Kim

Dielectric properties of sol-gel derived $\text{Ba}_{0.5}\text{Sr}_{0.5}\text{TiO}_3$ thin films.

S. Lahiry, V. Gupta, and K. Sreenivas

C-V characteristics of $\text{Bi}_4\text{Ti}_3\text{O}_{12}$ thin films and the fabrication of FEFET devices.

H. Wang, Z. Wang, S.C. Shang, and M. Wang

Microstructures of interface between IR base electrode and poly-Si

for stacked capacitors.

N. Izumi, Y. Fujimori, T. Nakamura, and A. Kamisawa

How to circumvent measuring artifacts in the characterization of ferroelectric thin films.

L. Schneider-Störmann, S. Tiedke, and O. Lohse

Ferroelectric properties of $\text{Pb}(\text{Zr,Ti})\text{O}_3$ -films on technical substrates.

R. Klarmann, W. Biegel, and B. Stritzker

Obtaining of the films of lead titanate processing ferroelectric properties.

A.M. Khoviv, A. Sidorkin, S.O. Yatsenko, and O.B. Yatsenko

Microstructure-ferroelectric properties relationships in sol-gel prepared lanthanum modified lead titanate thin films.

M. Alguero, M.L. Calzada, E. Snoeck, and L. Pardo

MEMORIES

Characterization of sol-gel derived SBT thin film on platinum electrodes for high density FRAM application

J.H. Lee, Y.S. Choi, W.S. Kim, C.E. Kim, W.S. Yoo, B.Y. Kim, and D.Y. Yang

Ferroelectric materials for the next generations of ULSI DRAM applications.

B.M. Goltsman, and V.K. Yamarkin

MONTREUX PAPERS

Electrical properties of SrTiO₃ based MOS structures for DRAM applications.

R. Thomas, and D.C. Dube

The effects of lanthanide dopants on the ferroelectric properties of sol-gel derived PZT thin film for FRAM application.

Y.S. Choi, W.S. Kim, C.E. Kim, S.H. Kim, and H.S. Song

Effects of backend processes on ferroelectric properties of Pt/SrBi₂Ta₂O₉/Pt capacitor for nonvolatile memory.

Y.M. Kang, S.K. Hong, J.W. Kim, S.W. Lee, C.W. Suh, and J. Lee

Self-patterning nanoelectrodes for large capacity integrated ferroelectric thin film memories.

A. Pignolet, M. Alexe, J.F. Scott, C. Curran, N.D. Zakharov, and D. Hesse

Effect of grain size on degradation of Pt/PLZT/Pt capacitor.

K. Ogata, K. Suenaga, K. Horikoshi, H. Abe, K. Yoshizumi, H. Kato, and M. Mori

Fatigue characteristics of PZT capacitors with Ir/IrO_x electrodes.

T. Hase, T. Noguchi, Ki. Takemura, and Y. Miyasaka

Low-temperature preparation and characterization of Sr_xBi_{2+y}Ta₂O₉/SiO₂/Si structure for MFOS memory FET.

Y. Matsumuro, H. Sugiyama, M. Noda, and M. Okuyama

(BaSr)TiO₃ higher thin film

sputtering technology for giga-bit DRAM application.

K. Suu, T. Masuda, Y. Nishioka, and N. Tani

Fatigue induced evolution of the domain structure in PZT/YBCO epitaxial heterostructures.

V.Y. Shur, S.D. Makarov, N.Y. Ponomarev, E.V. Nikolaeva, E.I. Shishkin, L.A. Suslov, N.N. Salashchenko, and E.V. Klunov

The stress effect of the covered film for FRAM integration on Pt/PZT/Pt capacitor.

B.J. Koo, S.Y. Lee, D.J. Jung, B.H. Kim, S.I. Lee, and K.N. Kim

Process stability control of Pb(ZrTi)O₃ ferroelectric thin film sputtering for FRAM application.

K. Suu, T. Masuda, Y. Nishioka, and N. Tani

Degradation of perovskite thin films fabricated by pulsed YAG laser ablation.

M. Yoichio, S. Fujita, A. Baba, H. Masumoto, and T. Hirai

THIN FILMS: PROCESSING AND MICROSTRUCTURE

Preparation of Ba₂NazNb₅O₁₅ thin films by pulsed laser ablation and their characterization.

S. Ando, S. Okamura, and T. Tsukamoto

Control of the composition of (Pb,Ti)O₃ and Pb(Zr,Ti)O₃ thin films obtained by R.F. magnetron sputtering using a new design of target.

V. Courtois-Lefort, D. Remiens, M. Descamps, and B. Thierry

Local crystallization of sol-gel BaTiO₃ thin films.

C. Gillot, C. Dumas, O. Bidault, P. Sibillot, and M. Maglione

Structural characterization of sol-gel deposited SrBi₂Nb₂O₉ thin film on (001)SrTiO₃ single crystal.

C. Legrand, J.H. Yi, P. Thomas, R. Guinebretiere, and J.P. Mercurio

Chemical fabrication SrBi₄Ti₄O₁₅ thin films.

L. Nibou, A. Aftati, M. El Farissi, and J.-P. Mercurio

Characterization of PZT thin films prepared by a modified sol-gel method.

B. Matthes, G. Tomandl, and G. Werner

TiO₂ thin films synthesized by the spray pyrolysis deposition (SPD) technique.

M. Okuya, N.A. Prokudina, K. Mushika, and S. Kaneko

Advanced preparation of Pb(Mg_{1/3}Nb_{2/3})O₃ thin film by sol-gel method.

G. Roiss, G. Tomandl, and G. Werner

Influence of the crystallization kinetics on the texture and ferroelectric characteristics of sol-gel PZT and BST thin films.

V.Ya. Shur, E.B. Blankova, A.L. Subbotin, and E.A. Borisova

Low-temperature processing of Pb(Zr_{0.53}Ti_{0.47})O₃ thin films from stable precursor sol.

H. Suzuki, T. Koizumi, Y. Kondo, and S. Kaneko

MONTREUX PAPERS

Seeded sol gel lead zirconate titanate thin films.

P.M. Vilarinho, A. Wu, I.M. Salvado, and J.L. Baptista

SrBi₂Nb₂O₉ thin films deposited by dip coating using aqueous solution.

S.M. Zanetti, E.R. Leite, E. Longo, and J.A. Varela

Auger analysis of PbTiO₃ films prepared by reactive electron beam co-evaporation.

S. Mochizuki, T. Mihara, and T. Ishida

Thin films of perovskite titanates grown by single source MOCVD.

M.A. Novozhilov, O.Yu. Gorbenko, V.A. Amelichev, J.A. Rebane, A.A. Molodyk, I.E. Korsakov, A.R. Kaul, and G. Wahl

Influence of substrate pre-annealing on the preferred orientation of lead magnesium niobate titanate thin films by sol-gel process.

J.H. Park, K.H. Yoon, and H. Kang

Characterization of on-stoichiometric PMN-PT films grown by laser ablation.

A.F. Cruz, J. Portelles, J.M. Siqueiros, and R. Machorro

Structural and electrical characterization of epitaxial Pb(ZrTi)O₃ heterostructures grown by laser ablation on SrTiO₃ and Al₂O₃ substrates: a comparative study.

M.G. Karkut, F. Le Marrec, R.K. Steinseth, C. Marechal, J.L. Dellis, F. Portemer, M. El Marssi, and R. Farhi

Phase transformations in sol-gel

prepared PZT and PT thin films upon isothermal treatments at different temperatures.

S.B. Majumder, B. Roy, D.C. Agrawal, and Y.N. Mohapatra

Superconductor-ferroelectric heterostructures.

C. Constantin, R. Ramer, M. Stegarescu, I. Matel, and L. Trupina

Low temperature growth of SrTiO₃ thin films on glass fiber laminate substrates.

X. Wang, and U. Helmersson

Amorphous (Ba,Sr)TiO₃ thin films and H₂ induced interfacial voltage by sol-gel and RF sputtering.

O.K. Tan, X.F. Chen, Q. Yan, and W. Zhu

Pulsed laser deposition of YBCO and novel oxide films for *in situ* studies by photoemission spectroscopy.

T. Schmauder, D. Ariosa, R. Gatt, S. Misra, B. Frazer, I. Vobornik, X.X. Xi, M. Gironi, G. Margaritondo, M. Onellion, and D. Pavuna

A novel integrated thin film capacitor realized by multilayer ceramic-electrode sandwich structure.

M. Grossmann, R. Slowak, S. Hoffmann, H. John, U. Berger, and R. Waser

Epitaxial growth of La-modified PbTiO₃ thin films on (0001) Al₂O₃ and (001) SrTiO₃ and (0001) SrTiO₃ substrates by rf magnetron sputtering.

U. Rabibisoa, P. Aubert, F. Bridou, O. Durand, M.C. Hugon, and B. Agius

ECR-PECVD of ferroelectric SrBi₂Ta₂O₉ thin films.

G.P. Choi, J.H. Ahn, W.Y. Choi, and H.G. Kim

The role of an intermetallic phase on the crystallization of lead zirconate titanate in sol-gel process.

Z. Huang, and R.W. Whatmore

Preferred orientation of solution derived (Pb,Ca)TiO₃ thin films on SrTiO₃ and MgO.

R. Jimenez, M.L. Calzada, and J. Mendiola

Development of stable PZT sputtering process using ex-situ crystallization and PZT/PT interface control technique.

K. Yamakawa, O. Arisumi, K. Okuwada, K. Tsutsumi, and T. Katata

Effect of the particle size in PZT precursor sols on the orientation of PZT thin films.

M.E. Vickers, and R.W. Whatmore

A model interface of Nb-STO/STO/Nb-STO thin films deposited on (100), (111) SrTiO₃ substrate with laser ablation technique.

S. Shibagaki, and K. Fukushima

in situ sputter deposition of PZT films: correlation between the lead incorporation and the growth temperature.

G. Velu, and D. Remiens

Preparation of barium-strontium titanate films by sol-gel route.

A.S. Sigov, K.A. Vorotilov, A.Y. Manokhine, and M.I. Yanovskaya

MONTREUX PAPERS

Laser induced crystallization of (Ba,Sr)TiO₃ thin films prepared by CSD techniques.

O. Baldus, U. Berger, S. Hoffmann, J. Gottmann, E.W. Kreutz, H. Pirch, and R. Waser

Step-flow growth of SrTiO₃ films.

S. Ohashi, M. Lippmaa, N. Nakagawa, K. Koinuma, and M. Kawasaki

Electrochemical formation of lead-zirconate-titanate thin films.

A.E. Prodromides, and P. Schmuki

Microstructure and defects of wurtzite structure thin films.

L. Sagalowicz, G. Fox, and M. Dubois

MOCVD of zirconia and lead zirconate titanate using novel zirconium precursors.

A.C. Jones, T.J. Leedham, P.J. Wright, D.J. Williams, and M.J. Crosbie

A-axis oriented SrBi₂Ta₂O₉ thin films controlled by radio frequency magnetron sputtering parameters.

S.-H. Lee, K.H. Yoon, J.-K. Lee, and H.-J. Jung

Growth of YBa₂Cu₃O_{7-x}/BaSr_{1-x}TiO₃/LaAlO₃ heterostructures by injection MOCVD.

J. Lindner, F. Weiss, J.-P. Sénateur, and V. Galindo

Chemical route to ferroelectric thin film capacitors.

J.-P. Mercurio, J.H. Yi, P. Thomas, and M. Manier

Fabrication and structural properties

of sol-gel derived Sr_{0.6}Ba_{0.4}Nb₂O₆ (SBN) films.

C.H. Luk, M.M.T. Ho, C.H. Mak, and K.H. Wong

Effects of a Bi₄Ti₃O₁₂ buffer layer on SrBi₂Ta₂O₉ thin films prepared by the metal organic solution deposition technique.

G.D. Hu, J.B. Xu, I.H. Wilson, W.Y. Cheung, and N. Ke

Preparation and characterization of conductive LaNiO₃ electrodes for ferroelectric capacitors by a modified sol-gel technique.

G.D. Hu, I.H. Wilson, J.B. Xu, W.Y. Cheung, and N. Ke

Stability of Pt/metal bilayer metallizations on SiO₂/Si and TiN/Si substrates.

J. Rajni, M. Fahim, V. Gupta, C. Jagdish, and K. Sreenivas

Low temperature process by heat treatment of SrBi₂TaNbO₉/Bi₂O₃/SrBi₂TaNbO₉ heterostructure fabricated by radio frequency magnetron sputtering.

Y.B. Park, J.W. Park, and J.K. Lee

Preparation and properties of Mn- or Nb-doped Bi₄Ti₃O₁₂ thin films by chemical solution deposition.

H. Maiwa, and N. Ichinose

Analysis of the electron-beam-induced reaction in precursor thin films of ferroelectric SrBi₂Ta₂O₉.

S. Okamura, and T. Shiosaki

Refinement of Pb(Zr,Ti)O₃ thin films grown by MOCVD.

M. Shimizu, H. Fujisawa, S. Hyodo, Y. Fujimoto, and H. Niu

Chemical solution deposition of Pb(Mg_{1/3}Nb_{2/3})O₃ thin film with PbTiO₃ seeding layers through alkoxide route.

H. Suzuki, K. Suzuki, H. Kamel, K. Ishikawa, T. Ota, and M. Takahashi

Structural and surface morphology characterizations of oriented LiNbO₃ thin films grown by polymeric precursor method.

V. Bouquet, E. Leite, and E. Longo

Pulsed laser deposition of lead zirconate titanate piezoelectric thin films from different targets.

F. Craciun, M. Dinescu, P. Veradi, G. Galassi, and A. Costa

Preparation of PZT, PLZT and Bi₄Ti₃O₁₂ thin films from oxide precursors.

E.B. Araujo, and J.A. Eiras

BULK MATERIALS: PROCESSING, MICROSTRUCTURES

Zirconium titanate powders and ceramics obtained via polymeric precursors.

A. Bianco, G. Gusmano, R. Freer, and P. Smith

Formation and properties of semi-conducting barium titanate doped with titanium compounds and nitrides.

L.L. Kovalenko, O.I. V'Yunov, and A.G. Belous

Investigations on the synthesis of Bi₃NbTiO₉ ceramics.

A. Lisinska-Czekaj, D. Czekaj, and M.F. Kuprianov

MONTREUX PAPERS

Evidence of dissolution-precipitation mechanism in hydrothermal synthesis of barium titanate powders.

P. Pinceloup, C. Courtois, J. Vicens, A. Leriche, and B. Thierry

Reactive sintering of phosphorous coated BaTiO₃.

J.F. Fernandez, A.C. Caballero, C. Moure, P. Duran, P. Florian, and J.-P. Coutures

Preparation and properties of (Ba_{0.6}Sr_{0.4})Bi₂Ta₂O₉ ceramic.

H.Y. Zhang, Z.Z. Huang, H.L.W. Chan, K.W. Kwok, and C.L. Choy

Influence of additives on the grain size of barium titanate.

E. Brzozowski, and M.S. Castro

Sintering of PZT powders in MW furnace at 2.45 GHz.

A. Goldstein, and M. Kravchik

Fabrication of piezoelectric particle dispersed ceramic nanocomposite.

H.J. Hwang, M. Toriyama, and M. Sando

The features of synthesis and microstructural investigations of semiconducting ceramics CuxNi_{1-x}yCo_{2y}Mn_{2-y}O₄.

I. Hadzaman, M. Kravtsiv, and O. Shpotyuk

Low temperature sintering of PZT powders coated with Pb₅G₃O₁₁ by sol-gel method.

T. Inoue, T. Hayashi, and Y. Akiyama

Crystal structure and morphology of TiO₂ thin films produced from Ti(i-

OPr)₄ by spray pyrolysis deposition.

S. Kaneko, N. Prokudina, M. Okuya, and K. Murakami

Systemic approach as a method for controlling properties of polycrystalline ceramic materials.

S. Kramarov, L.M. Katsnelson, T.K. Kusnetsova, M.I. Kovalenko, and O.V. Garbus

Crystal and microstructure of manganese-doped barium titanate ceramics sintered and annealed under various atmospheres.

H.T. Langhammer, T. Müller, K.H. Felgner, and H.-P. Abicht

Aqueous processing of barium titanate ceramics.

A. Neubrand, M. Bürgers, R. Lindner, and D. Lupascu

The influence of dopes on the microstructure and electrical properties of semiconducting BaTiO₃.

I. Loujetskii, A. Kovalskiy, and O. Mrooz

Non-isothermal sintering of Mn doped ZnO.

J. Han

Tape casting of piezo ceramic/polymer composites.

S. Schwarzer, and A. Roosen

Preparation of barium strontium titanate particles by vapor phase hydrolysis of precursors formed from alkoxide-hydroxide.

T. Hayashi, and H. Shinozaki

Processing and sintering of fine ceria gadolinia-yttria stabilized zirconia powders.

A. Tsoga, A. Naoumidis, W. Jungen, and D. Stöver

Synthesis of nobel structured PZT fibers.

A. Towata, H.J. Hwang, and M. Sando

Oxide slurries stability and powders dispersion: optimization with zeta potential measurements and rheological measurements.

S. Vallar, D. Houivet, D. Kervadec, and J.-M. Hausonne

Bismuth titanate from co-precipitated precursors - a thermal study of pH dependence on stoichiometry.

A. V. Prasada Rao, and M. Suresh

New functional ceramic deposition method for MEMS.

J. Akedo, M. Ichiki, and R. Maeda

Fabrication of PZT thick films on silicon substrates for piezoelectric actuator.

J. Yongbae, Y. Jeon, C. Lee, H. Song, K. No, S. Kim, D. Yoon, H. Hwang, and J. Park

Homogenization mechanism of perovskite solid solutions.

K. Kakegawa

Parameters influencing PZT thick films densification.

J.B. Véchembre

Alternative processing routes for bulk piezoelectric devices.

D.H. Pearce, and T.W. Button

Templated grain growth of perovskite ferroelectrics.

P.W. Rehrig, C. Duran, E.M. Sabolsky, S. Trolrier-McKinstry, and G.L. Messing

MONTREUX PAPERS

Growth and characterization of lead-free single crystal piezoelectrics.

Y.-M. Chiang, G.W. Farrey A. Soukhovjak, S. Sheets, N.W. Hagood, and G. Zelenka

Low-temperature sintering of Nb₂O₅-added Pb(Zr,Ti)O₃ ceramics.

K. Murakami, Y. Niwa, T. Kurita, X. Wang, and S. Kaneko

Hydrothermal synthesis of PZT powders; influence of processing parameters on powder characteristics and sintering behavior.

M. Traianidis, C. Courtois, A. Leriche, and B. Thierry

Nanosized LaFeO₃ powders from the thermal decomposition of a heteronuclear complex for electroceramic applications.

E. Traversa, M. Sakamoto, H. Aono, and Y Sadaoka

Hydrothermal synthesis and sintering of electroceramics.

A. Dias, V.T.L. Buano, V.S.T. Ciminelli, and R.L. Moreira

A study of formation and degradation of partially stabilized zirconium dioxide.

A.N. Makarenko, A.G. Belous, and E.V. Pashkova

Microstructural and dielectric properties of ceramics based on tetragonal tungsten bronze.

S. Vallar, J.El Fallah, and J.-M. Haussonee

Stability and single crystal growth of dielectric materials containing lead under hydrothermal condi-

tions.

K. Yanagisawa, J.C. Randon-Angeles, H. Kanai, and Y. Yamashita

Crystallization behavior of PZT-PFN powders from nitrate solutions.

Y. Yoshikawa

Laser heat pedestal growth method tested by PAC technique for the presence of oxygen vacancies in SrHfO₃ fiber.

P. De la Presa, A. Alonso, A. Lopez-Garcia, S.L. Cuffini, J.A. Guevara, M.R.B. Andreetta, A.C. Hernandez, and YU.P. Mascaraenhas

Iron doping effect on composition and microstructure of Bi₂.05Sr_{1.9}Ca_{1.05}(Cu_{1-x}Fe_x)₂O_{8+d}(0≤x≤0.15) samples.

C. De Boeck, P.H. Duvigneaud, and D. Ciurchea

Sintering of solid solutions Pb_{0.88}Ba_{0.08}Sr_{0.04}Ti_xZr_{1-x}O₃, 0<x<0.55 mol% and their properties.

L.E. Pustovaya, Y.N. Zakharov, V.A. Babanskikh, and V.Z. Borodin

Solubility of rare-earth (La, Sm, Dy, Ho, and Er) and Mg into BaTiO₃.

H. Kishi, J. Sugino, H. Ohsato, N. Kohzu, Y. Iguchi, and T. Okuda

The use of nanodispersed powders for the preparation of PTC-ceramics.

D. Grützmann, J. Böer, C. Jana, and W. Burckhardt

TEM observation of a reactive template for textured

Bi_{0.5}(Na,K)_{0.5}TiO₃ polycrystals.

Y. Seno, and T. Tani

Dynamics of SrTiO₃ surface during wet etching and high-temperature annealing.

M. Lippmaa, A. Ohtomo, K. Takahashi, T. Sato, M. Iwatsuki, H. Koinuma, and M. Kawasaki

Solution-precipitation of fine powders of PbTiO₃.

K.J. Stanly, K. Jayan, J.P. Selvam, K. Sivanandan, P.K. Girija, and V. Kumar

The effect of certain technological additions on the formation of the microstructure in the PZT ferroceramics.

S.O. Kramarov, T.G. Protsenko, and A.A. Grekov

A study of substitution of yttrium in BaTiO₃ ceramics.

J. Zhi, A. Chen, Yu Zhi, P.M. Vilarinho, and J.L Baptista

XPS investigation of surface properties of Ba(1-x)Sr_xTiO₃ powders prepared by the low temperature aqueous synthesis.

M. Viviani, M.T. Buscaglia, R. Parodi, G. Gemme, and A. Dacca

Sintering and grain growth of PMN and PMNT ceramics.

H. Yamada

Effect of pH on the formation of stoichiometric oxalate precursors for barium and strontium titanates.

A.V. Prasada Rao, and M. Suresh

TG-DTA-MS studies on the sythetic mechanism of BaTiO₃ micro

MONTREUX PAPERS

powders prepared by liquid packaging method.

L. Chang-Wei, X. Jun-Ming, X. Tong-Gen, L. Chen-Ern, Y. Xue-Hua, and C. Yun-Xian

Formation mechanism and phase transitions of lead scandium niobate ceramics doped with rare-earth oxides.

M. Dambekaline, I. Brante, and A. Sternberg

Phase evolution and densification behavior of PBN ceramics.

C.V. Do Camo, J.M. Pova, J.A. Eiras, and D. Garcia.

MICROWAVE MATERIALS, PROPERTIES AND APPLICATIONS

Phases in (Zr,Sn)TiO₄ microwave dielectric ceramics.

D. Houivet, J.El. Fallah, and F.J.M. Haussonne

Ba/La order in the Ba_{6-0x}La_{8+2x}/eTi₁₈O₅₄ microwave dielectrics.

D. Mercurio, M. Abou-Salama, and J.-P. Mercurio

Effects of excess TiO₂ on the microwave dielectric properties of the Ca_{2/5}Sm_{2/5}TiO₃-Li_{1/2}Ln_{1/2}TiO₃ (Ln=Sm, Nd) ceramics.

W.S. Kim, K.H. Yoon, and E.S. Kim

Dielectric relaxation in PLT (Pb_{1-x}CaxTiO₃) in the microwave region (0.1-109HZ).

L.A. Bassora, and J.A. Eiras

Whispering gallery mode microwave characterization of BaCe₂Ti₃O₁₁, BaCe₂Ti₄O₁₃ and

BaCe₂Ti₅O₁₅ ceramic dielectric resonators.

R. Ratheesh, H. Sreemoolanadhan, M.T. Sebastian, J. Harnett, M. Tobar, and D.G. Blair

PbO-doped Ba_{3.75}Nd_{9.5}Ti₁₈O₅₄ microwave dielectric resonators.

R. Ubic, I.M. Reaney, W.E. Lee, J. Samuels, and E. Evangelinos

Microwave dielectric relaxation in relaxor ferroelectrics and related disordered materials.

V. Bovtun, M. Leshchenko, Y. Poplavko, and Yu. Yakimenko

The effect of cerium oxide doping on barium strontium titanate.

L.H. Chiu, L.C. Sengupta, C. Hubbard, and M. Cole

Microwave dielectric properties of the (1-c)Ca(Mg_{1/2}W_{1/2})O₃-cCaTiO₃ system.

J.H. Yang, and W.K. Choo

Microwave dielectric properties of (Li,Nd)TiO_c - (Na,Ln)TiO₃ (Ln = La, Nd, Sm) ceramic system.

N. Ichinose, and N. Chida

Microwave dielectric properties of (Y_{2-x}R_x)BaCuO₅ (R=rare-earth) solid solutions.

H. Ogawa, M. Watanabe, H. Ohsato, and C. Humphreys

New temperature stabilized MW dielectrics with perovskite-like structure based on Sm-containing systems.

A.G. Belous, and O.V. Ovchar

Modified Ba_{6-3x}Nd_{8+2x}Ti₁₈O₅₄ microwave dielectric ceramics.

X.M. Chen, and Y.J. Wu

BULK MULTILAYERS

Optimization of lamination and porosity defects in multilayer capacitor fabrication.

A.W. Taverno, R. Strevens, and A.J. Bell

3-dimensional FEM simulations of resonances in the impedance characteristic of ceramic multilayer capacitors.

K. Prume, T. Leuerer, and R. Waser

Modeling of multilayer piezoelectric structures.

R. Desmare, L.P. Tran-Huu-Hue, F. Levassort, W. Wolny, and M. Lethiecq

Characteristics of electromechanical solid state multilayer actuators.

P. Pertsch, M.-J. Pan, V.R. Vedula, S. Yoshikawa, and T.R. Shrout

Effects of additives on sintering behavior of Ni internal electrode of BaTiO₃-based multilayer ceramic capacitors.

T. Takahashi, Y. Nakano, H. Shoji, H. Matsushita, H. Ogawa, A. Onoe, H. Kanai, and Y. Yamashita

MAGNETIC AND SUPERCONDUCTING MATERIALS

Burgers relationships for 2201 phase precipitation in 2223 HTSC films.

D. Ciurchea, J.F. De Marneffe, L. Szabo, P.H. Duvigneaud, and R. Deltour

The new magnetic ceramic materials based on compounds of Cu-Cr-Te and Cu-In-Cr-Se systems.

MONTREUX PAPERS

*T.I. Koneshova, A.A. Babitsina,
and T.A. Emel'Yanova*

Use of manganese zinc ferrites in high frequency ultrasonics transducers.

V.M. Sarnatski

Thermomechanical behavior and modellization of melt-textured YBaCuO composites containing <<Ag>> and/or <<2121>> particles.

*F. Tancrét, J.-M. Haussonee,
and F. Osterstock*

Superconductivity of new reduced tantalates with a layered perovskite structure.

K. Toda, T. Teranishi, and M. Sato

Magnetic field effect on the complex permeability for a Mn-Zn ferrite and its composite materials.

T. Tsutaoka, and T. Kasagi

Electrical and magnetic properties of LaBi₄FeTi₃O₁₅.

A.R. James

High pressure synthesis of Hg₁₂₂₃ superconductor under highly oxidizing atmosphere.

*N. Yoshida, S. Adachi, T. Tatsuki,
T. Tamura, K. Tanabe, S. Fujihara, and T. Kimura*

Magnetic glass ceramics - preparation and properties.

R. Müller, C. Ulbrich, W. Schüppel, H. Steinmetz, and E. Steinbeiss

Tungsten-containing superconducting phase.

T.N. Kol'tsova, G.D. Nipan, K.S. Gavrichev, A.I. Firov, and P. Manca

Interfacial reaction between Ag and NdBa₂Cu₃O_{7- ∞} superconductor prepared by low-temperature process.

S. Fujihara, G. Murakami, T. Kimura, and Y. Masuda

CALL FOR PAPERS: SPECIAL ISSUE ON APPLICATIONS OF FERROELECTRICS

The *IEEE Transactions on Ultrasonics, Ferroelectrics, and Frequency Control* is planning a special issue on Applications of Ferroelectrics, featuring expanded versions of papers presented at ISAF XI, held in Montreux, Switzerland, 24-27 August 1998, and combining these with submitted papers on topics including, but not limited to,

- ferroelectric single crystals
- ferroelectric thin devices
- ferroelectric capacitors
- piezoelectric sensors and actuators
- variable conductivity devices
- infrared and microwave devices
- ferroelectrics for microsystems
- nonlinear optical devices
- biomaterials and glass ceramics
- novel concepts for synthesizing and manufacturing ferroelectric materials.

Contributed papers should be sent to the Editor-in-Chief:

William D. O'Brien, Jr., Department of Electrical and Computer Engineering
University of Illinois, 405 North Matthews, Urbana, IL 61801 USA

Guest editor for this special issue will be Ahmad Safari, Distinguished Professor, Department of Ceramic and Materials Engineering, Center for Ceramic Research, Rutgers, The State University of New Jersey. All papers will be subject to the normal peer-review process of the *IEEE UFFC Transactions*.

The submission deadline is **1 March 1999** and the expected publication date for the special issue is early 2000.

UPCOMING MEETINGS

16th Meeting on Ferroelectric Materials and Their Applications (FMA 16)**26-29 May 1999****Co-Op Inn Kyoto, Kyoto, Japan****Topics**

- New phenomena and measurement methods
- Preparation, properties, and evaluation of materials: single crystal, ceramics, amorphous, thin film, polymer, liquid crystal, composite, etc.
- Application: capacitor, high-frequency dielectrics, sensor, PTC thermistor, piezoelectric (surface acoustic wave device, filter, actuator, ultrasonic motor, etc.), optical, pyroelectric, memory device, recording device, memory, etc.

Abstracts

Deadline: 20 February 1999

For instructions how to prepare the abstracts, see home page:

<http://msw3.aist-nara.ac.jp/ms/LABs/shiosaki/fma/index.html>

Please send abstracts to: Prof. T. Shiosaki, Graduate School of Materials Science, Nara Institute of Science and Technology, Takayama, Ikoma, 630-0101, Japan. The Program Committee will inform authors about the acceptance or rejection of their papers around the end of March. All accepted abstracts will be printed and distributed on the first day of the meeting.

Publication of Papers

Authors are encouraged to submit the papers presented at FMA 16 to the special issue of the *Japanese Journal of Applied Physics (JJAP)*. Please send manuscripts to Prof. Shiosaki by 6 May 1999. After being reviewed and accepted for publication in the *JJAP*, the papers will be published at the end of September 1999.

Language

Papers are presented in Japanese and also in English.

ContactSteering Committee: Tadashi Shiosaki, fax: +81-743-72-6049, e-mail: shiosaki@ms.aist-nara.ac.jpProgram Committee: Masanori Okuyama (Osaka University), fax: +81-6-850-6341,
e-mail: okuyama@ee.es.osaka-u.ac.jp**3rd Korea-Japan Conference on Ferroelectrics****24-26 June 1999****Kyongju, Korea**

We are pleased to announce that the 3rd Korea-Japan Conference on Ferroelectrics will be held in Kyongju, Korea, following the very successful previous ones, the first one at the Pusan National University, 1994, and the second at the Hokkaido University, 1996. The conference shall cover all areas of ferroelectrics in both theory and experiment, from basics to applications. The primary goal is to promote binational cooperation between Korea and Japan and to exchange new ideas and results on ferroelectrics research.

Presentations, oral and poster, of original research on ferroelectrics and related materials are cordially invited. Students and young researchers are particularly welcome.

UPCOMING MEETINGS**Committees**

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Abstracts

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Prospective authors of oral as well as poster presentations should send abstracts in camera-ready form typewritten on a white sheet of good quality paper to Prof. Y. H. Jeong, Department of Physics, Pohang University of Science and Technology, Pohang, Kyungbuk 790-784, Korea, phone: + 82-562-279-2078, fax: + 82-562-279-3099, e-mail: yhj@postech.ac.kr

Proceedings

The complete paper to be included in the proceedings should be submitted on 24 June 1999 at the registration desk. After proper refereeing, the papers will be published in a special issue of the *Journal of Korean Physical Society*.

Language

The official language is English. No translation services will be provided.

Contact

Prof. Y. H. Jeong, e-mail: yhj@postech.ac.kr

Ferroelectricity Newsletter

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MRS PUBLICATIONS

NEW RELEASES FROM THE MATERIALS RESEARCH SOCIETY**MRS Adds New Volume to Series on Ferroelectric Thin Films**

The newest volume in a continuing series from the Materials Research Society (MRS), *Ferroelectric Thin Films VI*, documents symposium reports from the 1997 MRS Fall Meeting in Boston, MA, and contains 81 papers, 529 pages.

The volume presents a wide range of topics spanning basic academic research to applied integration issues. Fundamental materials studies, new growth methods, device and materials integration research, and developments in the design and growth of new materials, all involving epitaxial, polycrystalline and nanocrystalline ferroelectric thin films, are featured. In addition, since ULSI chip manufacturers are seriously considering incorporating ferroelectric DRAM technology into existing fabrication facilities, the industrial interest and resulting research is causing an explosion in ferroelectrics. To that end, the volume focuses on the latest technical information on ferroelectric thin films from academia, government organizations, and industry. Topics include: high-permittivity DRAM materials; domains and size effects; barriers and electrodes; bilayered ferroelectrics; Pb-based ferroelectrics; microwave and optical devices; materials for piezoelectric MEMs; and novel ferroelectric devices.

Edited by Randolph Edward Treece (Superconducting Core Technologies, Inc.), Robert E. Jones (Motorola Inc.), Christopher M. Foster (Argonne National Laboratory), Seshu B. Desu (Virginia Tech), and In K. Yoo (Samsung Advanced Institute of Technology), *Ferroelectric Thin Films VI* (ISBN: 1-55899-398-3) is Volume 493 in the MRS Symposium Proceedings Series. It is available in hardcover or microfiche for \$62.00 (MRS members), \$71.00 (US list), and \$82.00 (Non-US list).

Covalently Bonded Disordered Thin Films Explored in New Volume from MRS

The current and potential impact of covalently bonded disordered thin films is enormous. These materials are amorphous-to-nanocrystalline structures made from light atomic weight elements from the first row of the periodic table. Examples include amorphous tetrahedral diamond-like carbon, boron nitride, carbon nitride, boron carbide, and boron-carbon nitride. These materials are under development for use as novel low-power, high-visibility elements in flat-panel display technologies, cold-cathode sources for microsensors and vacuum microelectronics, encapsulants for both environmental protection and microelectronics, optical coatings for laser windows, and ultrahard tribological coatings. Researchers from 17 countries and a broad range of academic institutions, national laboratories, and industrial organizations come together in this new volume from MRS, *Covalently Bonded Disordered Thin-Film Materials*, to report on the status of key areas and recent discoveries. More specifically, the volume is organized into five sections. The first four highlight ongoing work primarily in the area of amorphous/nanocrystalline (disordered) carbon thin films: theoretical and experimental structural characterization; electrical and optical characterizations; growth methods; and cold-cathode electron emission results. The fifth section describes the growth, characterization, and application of boron- and carbon-nitride thin films.

Edited by M.P. Siegal (Sandia National Laboratories), W.I. Milne (Cambridge University), and J.E. Jaskie (Motorola Inc.), *Covalently Bonded Disordered Thin-Film Materials* (ISBN: 1-55899-403-3) documents symposium proceedings from the 1997 MRS Fall Meeting in Boston, MA, and contains 44 papers, 310 pages. Volume 498 in the MRS Symposium Proceedings Series, it is available in hardcover or microfiche for \$60.00 (MRS members), \$68.00 (US list), and \$79.00 (Non-US list).

New Volume from MRS Focuses on High-Performance Ceramic Materials in Electronics

Just published by MRS, *Chemical Aspects of Electronic Ceramic Processing* documents symposium reports from the 1997 Fall Meeting in Boston, MA, and contains 65 papers, 469 pages.

The use of high-performance ceramic materials in electronics holds the potential for the development of a wide array of novel, high-value products. These include: ferroelectric ceramic capacitors for ferroelectric nonvolatile random access memory (FRAM); high-dielectric capacitors for dynamic random access memory (DRAM); low-dielectric aerogels and mesoporous materials; electrooptical materials for waveguides, filters, and switches; electronic packaging and interconnects for microelectronics; and wide-bandgap materials for blue LEDs and high-temperature devices. The key to the application of any of these materials is the method of deposition (thin films) or fabrication (bulk). As in prior years, chemical vapor deposition (CVD) continues to be a popular area of research and is the subject

MRS PUBLICATIONS

of at least half of the papers in this volume. Particularly "hot" areas of research are new and improved precursors, delivery systems for low-vapor pressure precursors, and improved processing and materials properties. Papers are evenly divided between oxide ceramics and nonoxide ceramics. Solution processing of films is also a central theme. Using several techniques and chemistries, a wide range of materials are deposited with excellent properties. This technique holds the promise of replacing many expensive high-vacuum techniques with simpler and cheaper solution chemistry ceramics. Topics include: chemical vapor deposition of oxide ceramics; chemical vapor deposition of nonoxide ceramics; solution routes to ceramic materials; characterization and application of ceramic materials; and novel processing of ceramic materials—process characterization.

Edited by P.N. Kumta (Carnegie Mellon University), A.F. Hepp (NASA Lewis Research Center), D.B. Beach (Oak Ridge National Laboratory), B. Arkles (Gelest, Inc.), and J.J. Sullivan (MKS Instruments, Inc.), *Chemical Aspects of Electronic Ceramic Processing* (ISBN: 1-55899-400-9) is Volume 495 in the MRS Symposium Proceedings Series, and is available in hardcover or microfiche for \$62.00 (MRS members), \$71.00 (US list), and \$82.00 (Non-US list).

New Volume from MRS Examines Thin-Film Structures for Photovoltaics

Just published by MRS, *Thin-Film Structures for Photovoltaics* documents symposium reports from the 1997 MRS Fall Meeting in Boston, MA, and contains 49 papers, 312 pages.

Substantial progress has been demonstrated in developing thin-film-based II-VI, I-III-VI, and III-V semiconductors for photovoltaic (PV) devices. Success in these areas has also prompted research into thin (thickness $<20\mu\text{m}$) silicon solar cells. Thin-film PV devices require novel approaches to device design, deposition, and growth techniques, and large-area uniformity coupled with low-cost requirements. This volume addresses various issues in the design and fabrication of thin-film PV devices, deposition of semiconductors on low-cost substrates, nucleation and growth phenomena, interface and surface properties that influence film morphology and its structural, electrical, and optical properties. This volume also addresses process issues, such as individual layers during device fabrication. Topics include: silicon-based thin films; II-VI-based thin films, III-V-based thin films, and thin films—general.

Edited by Eric D. Jones (Sandia National Laboratories), Juris Kalejs (ASE Americas Inc.), and Rommel Noufi and Bhushan Sopori (National Renewable Energy Laboratories), *Thin-Film Structures for Photovoltaics* (ISBN: 1-55899-390-8) is Volume 485 in the MRS Symposium Proceedings Series, and is available in hardcover or microfiche for \$60.00 (MRS members), \$68.00 (US list), and \$79.00 (Non-US list).

To order, contact the Materials Research Society, Customer Services Department, 506 Keystone Drive, Warrendale, PA 15086, phone: +724-779-3003, fax: +724-779-8313

ASSESSING THE DEPTHS OF DEGRADATION

The National Physical Laboratory has published a technical report evaluating the degradation and fatigue properties of piezoelectric and magnetostrictive materials designed for continuous operation within demanding environments.

These materials are being developed as sensors and actuators for use under conditions of high electrical and mechanical stress, and high stress rate. Research programs, supported by the UK's Department of Trade and Industry and the European Commission, are developing techniques for quantifying the degradation of these materials under typical service conditions.

A variety of techniques, including acoustic, thermal, and optical imaging are being used to monitor degradation. The combination of adopting various complimentary methods allows better materials and products to be developed.

Further details on obtaining a copy of the report may be obtained from Markys Cain, National Physical Laboratory, Queens Road, Teddington TW11 0LW, United Kingdom, phone: +44- 181-943-6599, fax: +44-181-943-2989, e-mail: markys.cain@npl.co.uk

INDEX OF VOLUME 6, NUMBERS 1 - 4

Upcoming Meetings

Short Course on Ferroelectrics and Their Applications, Cranfield University, England	29 Mar-3 Apr 98	No.1, p.17
The Dielectrics Society 29th Annual Conference & The 4th UK Transducer Materials and Transducers Workshop, Canterbury, England	6-9 Apr 98	No.1, p.18
16th Conference on Crystal Growth and Epitaxy, Fallen Leaf Lake, California, USA	7-10 Jun 98	No.1, p.19
IEEE Conference on Electrical Insulation and Dielectric Phenomena (CEIDP98), Atlanta, Georgia, USA	25-28 Oct 98	No.2, p.12
Processing of High Dielectric Constant Materials for DRAMs, 45 International Symposium of the American Vacuum Society, Session EM12, Baltimore, Maryland, USA	2-6 Nov 98	No.2, p.12
Micro System Technologies 98, 6th International Conference and Exhibition on Micro Electro, Opto, Mechanical Systems and Components, Potsdam, Germany	1-3 Dec 98	No.2, p.13
International Conference on Solid State Crystals Materials Science and Applications, Zakopane, Poland	12-16 Oct98	No.3, p.16
11th International Symposium on Integrated Ferroelectrics (ISIF99), Colorado Springs, Colorado, USA	7-10 Mar 99	No.3, p.16
Transducers '99: 10th International Conference on Solid State Sensors and Actuators, Sendai, Japan	7-10 Jun 99	No.3, p.17
9th European Meeting on Ferroelectricity (EMF-9), Prague, Czech Republic	12-16 Jul 99	No.3, p.18
11th American Conference on Crystal Growth and Epitaxy, Tucson, Arizona, USA	1-6 Aug 99	No.3, p.19
Short Course on Crystal Growth, Tucson, Arizona, USA	31 Jul-1 Aug 99	No.3, p.19
16th Meeting on Ferroelectric Materials and Their Applications, Kyoto, Japan (FMA16)	26-29 May 99	No.4, p.35
3rd Korea-Japan Conference on Ferroelectrics, Kyungju, Korea	24-26 Jun 99	No.4, p.35

Conference Reports

10th International Symposium on Integrated Ferroelectrics, Monterey, California, USA	1-4 Mar 98	No.2, p..2
9th National Seminar on Ferroelectrics and dielectrics (NSFD-IX), New Delhi, India	8-12 Oct 96	No.3, p.2
6th Biennial Conference in Ferroelectric Liquid Crystals (FLC'97), Bretagne, France	20-24 Jul 97	No.3, p.9
Electroceramics VI, European Conference on Applications of Polar Dielectrics (ECAPD IV), 11th International Symposium on Applications of Ferroelectrics (ISAF XI), Montreux, Switzerland	24-27 Aug 98	No.4, p.2

Index of Conference Papers

10th International Symposium on Integrated Ferroelectrics (ISIF 98), Monterey, California, USA	1-4 Mar 98	No.1, p..2
COST 514 ACTION Workshop on Ferroelectric Thin Films, Parma, Italy	14-15 Apr 97	No.2, p..2
16th Conference on Crystal Growth and Epitaxy, Fallen Leaf Lake, California, USA	7-10 Jun 98	No.2, p..4
1997 Williamsburg Workshop on Ferroelectrics, Williamsburg, Virginia, USA	2-5 Feb 97	No.2, p..10
9th National Seminar on Ferroelectrics and Dielectrics (NSFD-IX), New Delhi, India	8-12 Oct 96	No.3, p.3
6th Biennial Conference in Ferroelectric Liquid Crystals (FLC'97), Bretagne, France	20-24 Jul 97	No.3, p.10
Electroceramics VI, European Conference on Applications of Polar Dielectrics (ECAPD IV), 11th International Symposium on Applications of Ferroelectrics (ISAF XI), Montreux, Switzerland	24-27 Aug 98	No.4, p.2

Special Reports

History: ISIF Memories Made Nonvolatile	No.1, p.2
20 Years of Ferroelectric Research at Tver University, Russia	No.1, p.15
Müser Festschrift	No.3, p.14

CALENDAR OF EVENTS 1999

Mar 7-10	• 11th International Symposium on Integrated Ferroelectrics (ISIF '99), Colorado Springs, Colorado, USA (see <i>Ferroelectricity Newsletter</i> , Vol. 6, No. 3, p. 16)
May 26-29	• 16th Meeting on Ferroelectric Materials and Their Applications (FMA 16), Kyoto, Japan (see p. 35)
Jun 7-10	• Transducers '99: The 10th International Conference on Solid-State Sensors and Actuators, Sendai, Japan (see <i>Ferroelectricity Newsletter</i> , Vol. 6, No. 3, p.17)
Jun 24-26	• 3rd Korea-Japan Conference on Ferroelectrics, Kyungju, Korea (see p. 35)
Jul 12-16	• 9th European Meeting on Ferroelectrcity (EMF-9), Prague, Czech Republic (see <i>Ferroelectricity Newsletter</i> , Vol. 6, No. 3, p. 18)
Jul 31- Aug 1	• Short Course on Crystal Growth, Tucson, Arisona, USA (see <i>Ferroelectricity Newsletter</i> , Vol. 6, No. 3, p. 19)
Aug 1-6	• 11th American Conference on Crystal Growth and Epitaxy, Tucson, Arizona, USA (see <i>Ferroelectricity Newsletter</i> , Vol. 6, No. 3, p. 19)
Aug 4-13	• 18th International Union of Crystallography and General Assembly, Glasgow, Scotland Gill Houston, crystal@glasconf.demon.co.uk or Chris Gilmore iucr99@chem.gla.ac.uk